



seit 1558

Strong-field physics meets quantum optics

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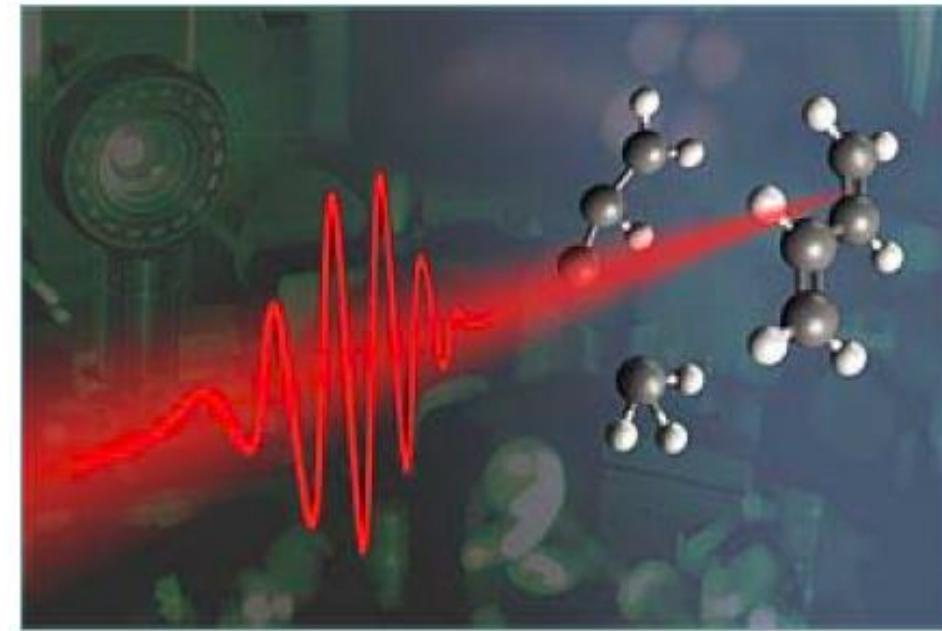
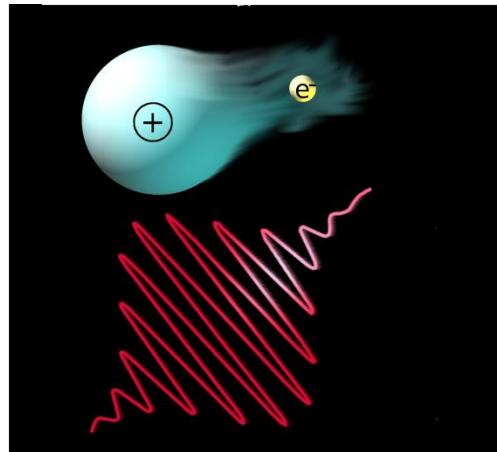
Abbe Center of Photonics

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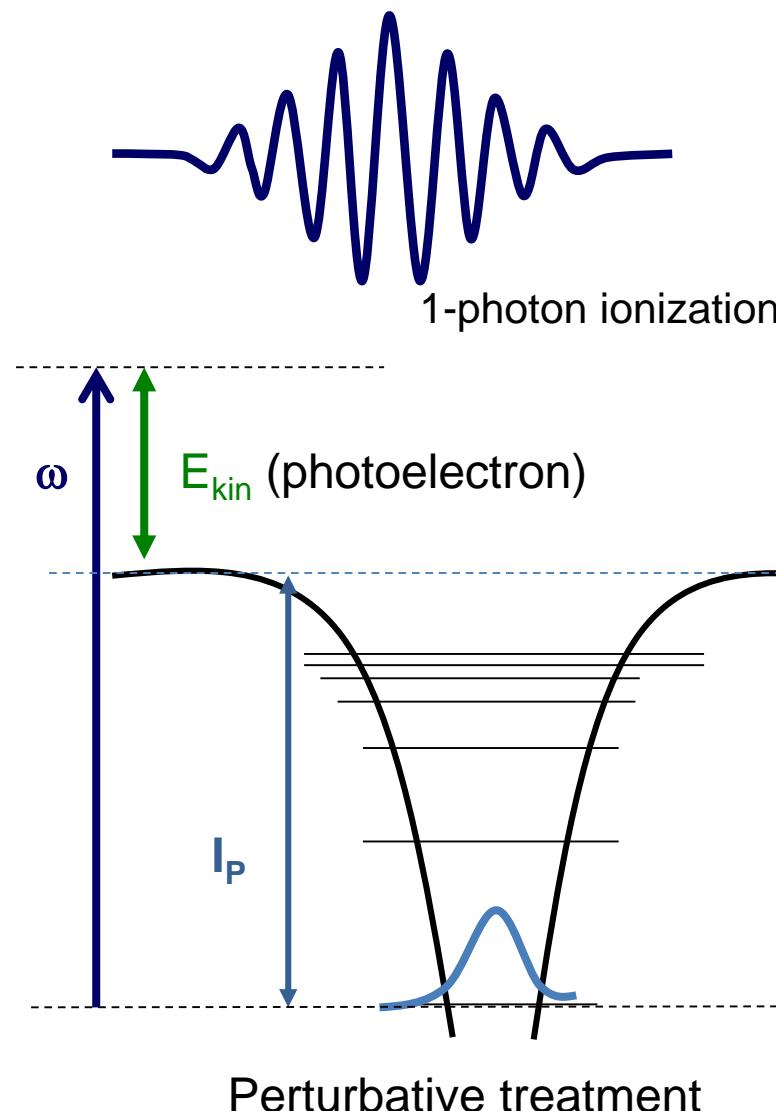


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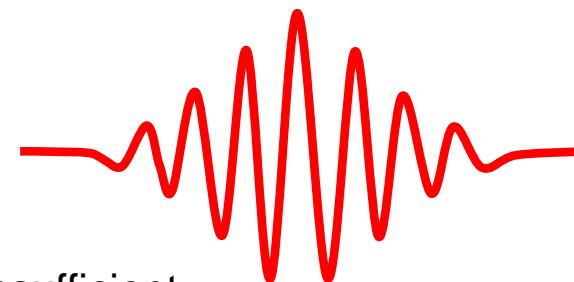


BASIC INTRODUCTION: STRONG-FIELD LIGHT-MATTER INTERACTION

Ionization



Ionization:
 $\omega > I_P$ vs. $\omega < I_P$



1 photon insufficient
for ionization
→ more than one photon
→ higher intensities

Strong-field ionization (low frequency limit)

Keldysh parameter

$$\gamma \equiv \sqrt{\frac{I_P}{2U_P}} = \omega\tau$$

$$= \frac{\tau_{tunnel}}{\tau_{optical}}$$

“slow” → tunneling

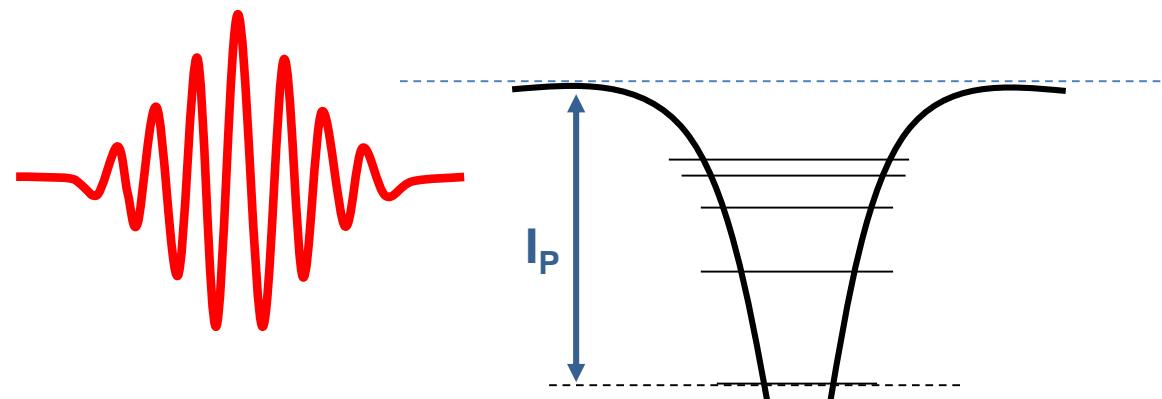
$$\gamma \ll 1$$

“fast” → multiphoton

$$\gamma \gg 1$$

$$\tau = \frac{v_{el}}{E_0} = \frac{\sqrt{2I_P}}{E_0} \quad \text{„tunneling time“}$$

$$U_P = \frac{(E_0)^2}{4\omega^2} \quad \begin{array}{l} \text{Ponderomotive potential} \\ (\text{„kin. energy of } e^- \text{ in laser field“}) \end{array}$$



Strong-field ionization: mechanisms

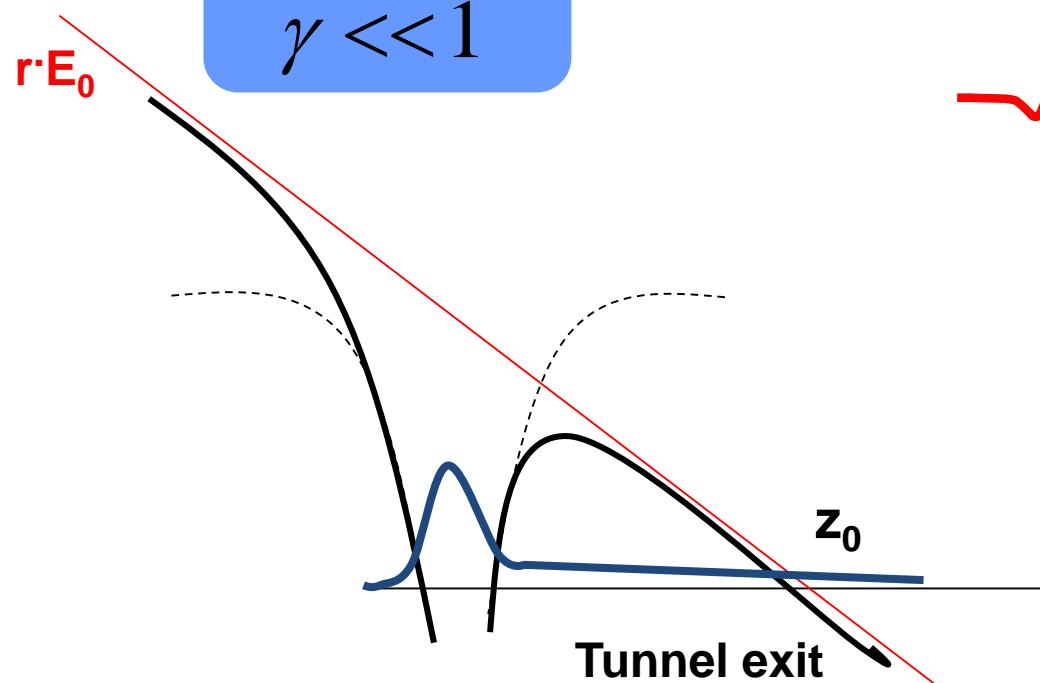
Keldysh parameter

$$\gamma = \sqrt{\frac{I_P}{2U_P}}$$

$$U_P = \frac{(E_0)^2}{4\omega^2} \quad \text{Ponderomotive potential}$$

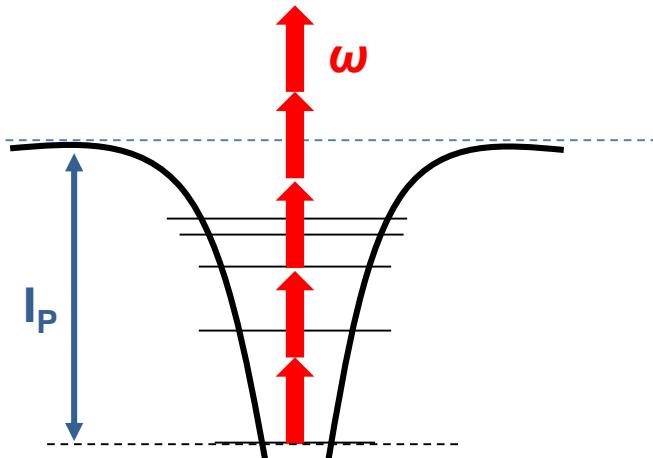
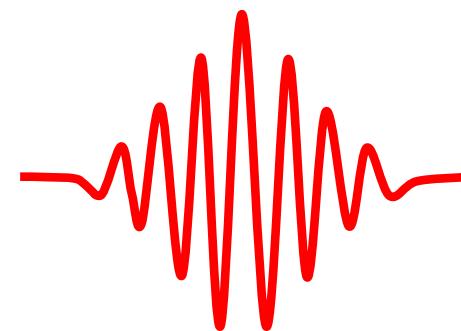
Tunnel regime

$$\gamma \ll 1$$

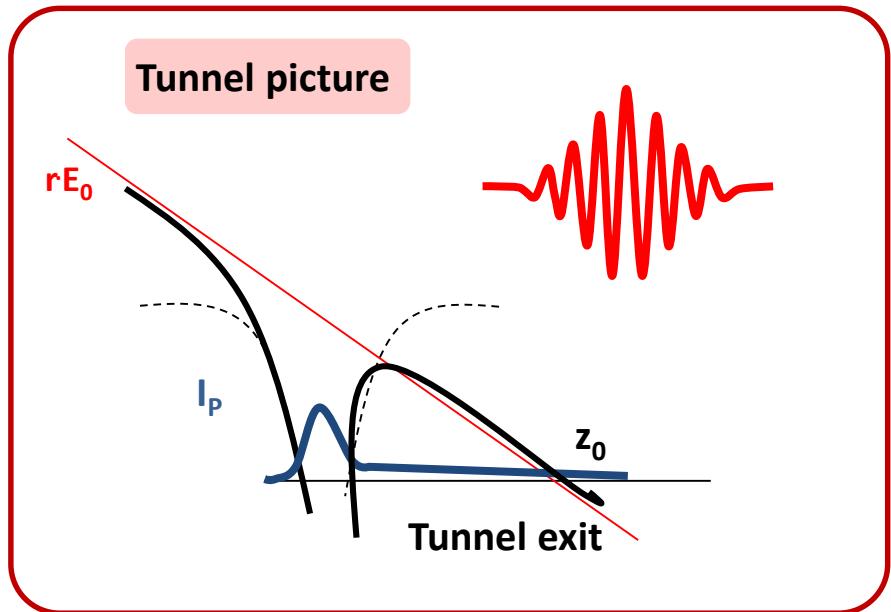


Multiphoton regime

$$\gamma \gg 1$$



Introduction: Strong-field physics



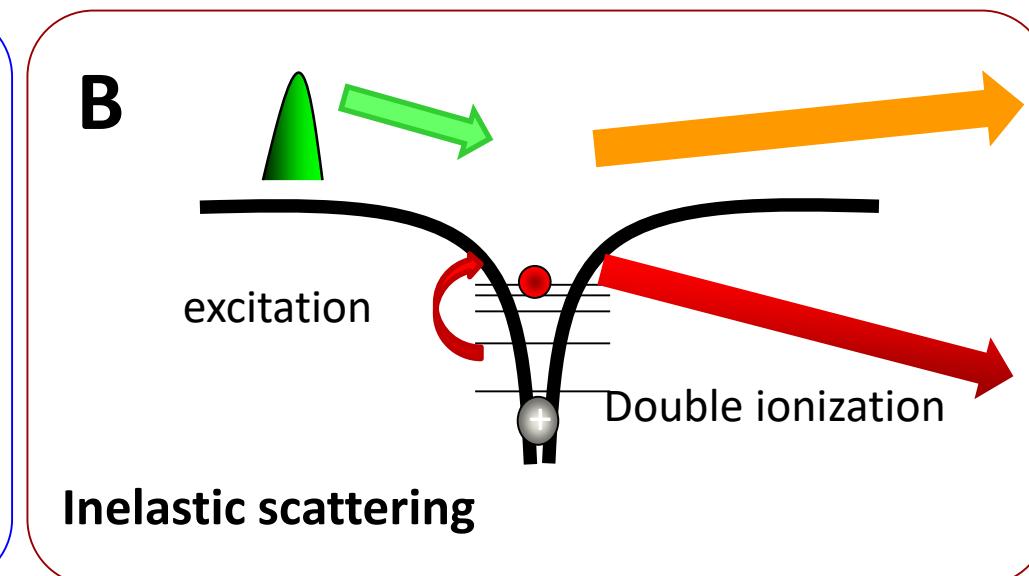
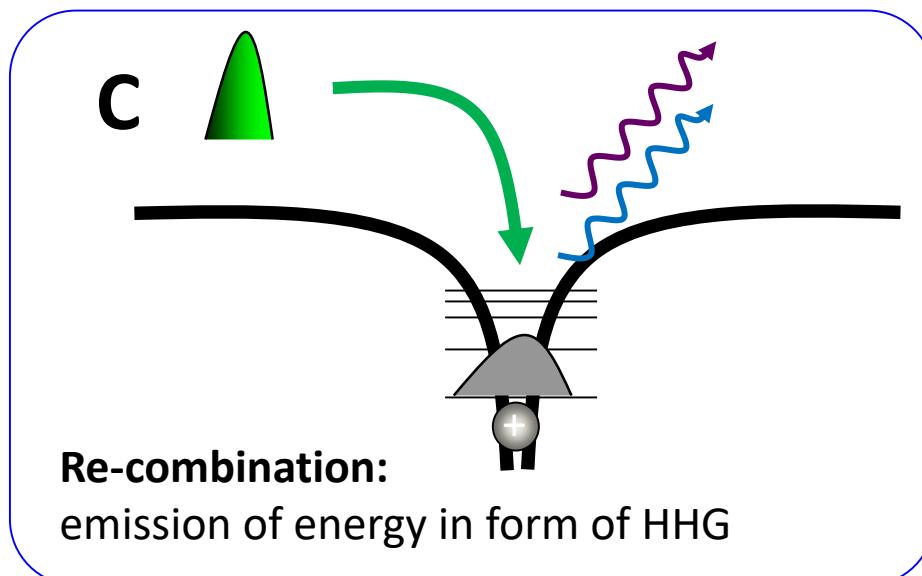
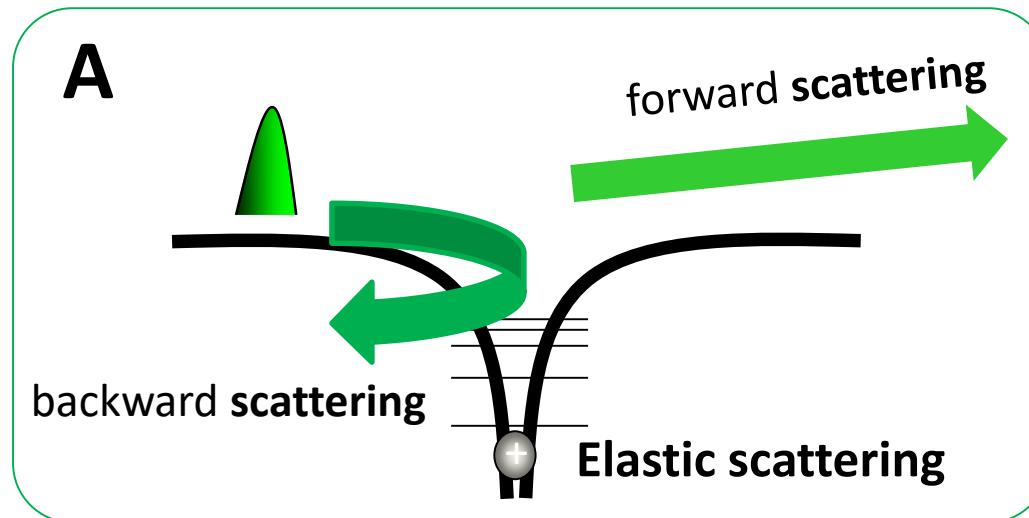
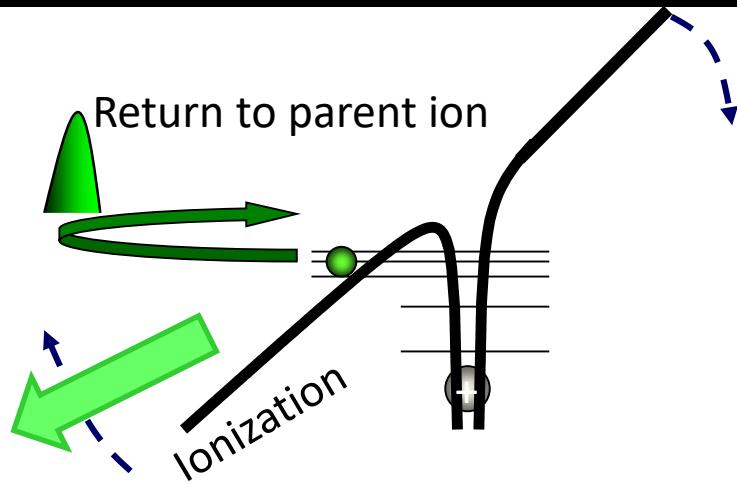
$$U_P = \frac{E^2}{4\omega^2}$$

Av. kin. energy of e^-
in the laser field

$$\tilde{\alpha} = \frac{E}{\omega^2}$$

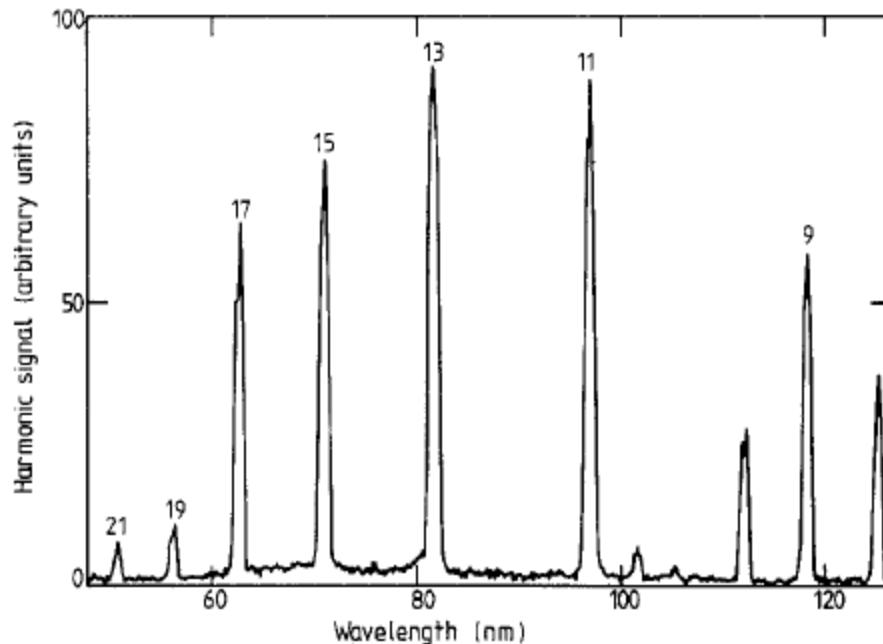
Quiver motion of e^-
in the laser field

What happens after ionization? Electron dynamics in intense laser fields



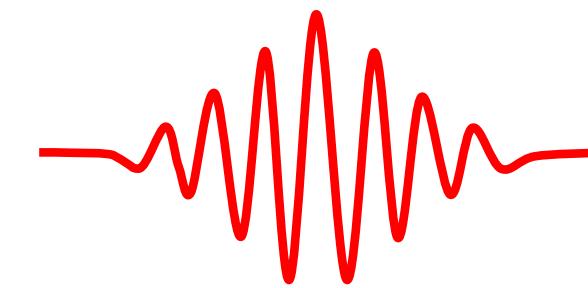
High-order harmonic generation

Lower-order (perturbative) harmonics decrease in intensity; high-order harmonics form a plateau



laser parameter:
1064 nm, ~ 30 ps, 3×10^{13} W/cm²

Figure 1. Harmonic spectrum obtained using a Xe gas jet showing all odd harmonics between 9 and 21. The peaks at 101, 112 and 125 nm are the second diffracted orders of the 21st, 19th and 17th harmonics respectively. The laser intensity was approximately 3×10^{13} W cm⁻² and the Xe pressure at the focal point was about 10 Torr.



M. Ferray, A L'Huillier, XF Li, LA Lompré, G Mainfray, C Manus,
“Multiple-harmonic conversion of 1064 nm radiation in rare gases”,
J Phys B. 21, L31 (1988)

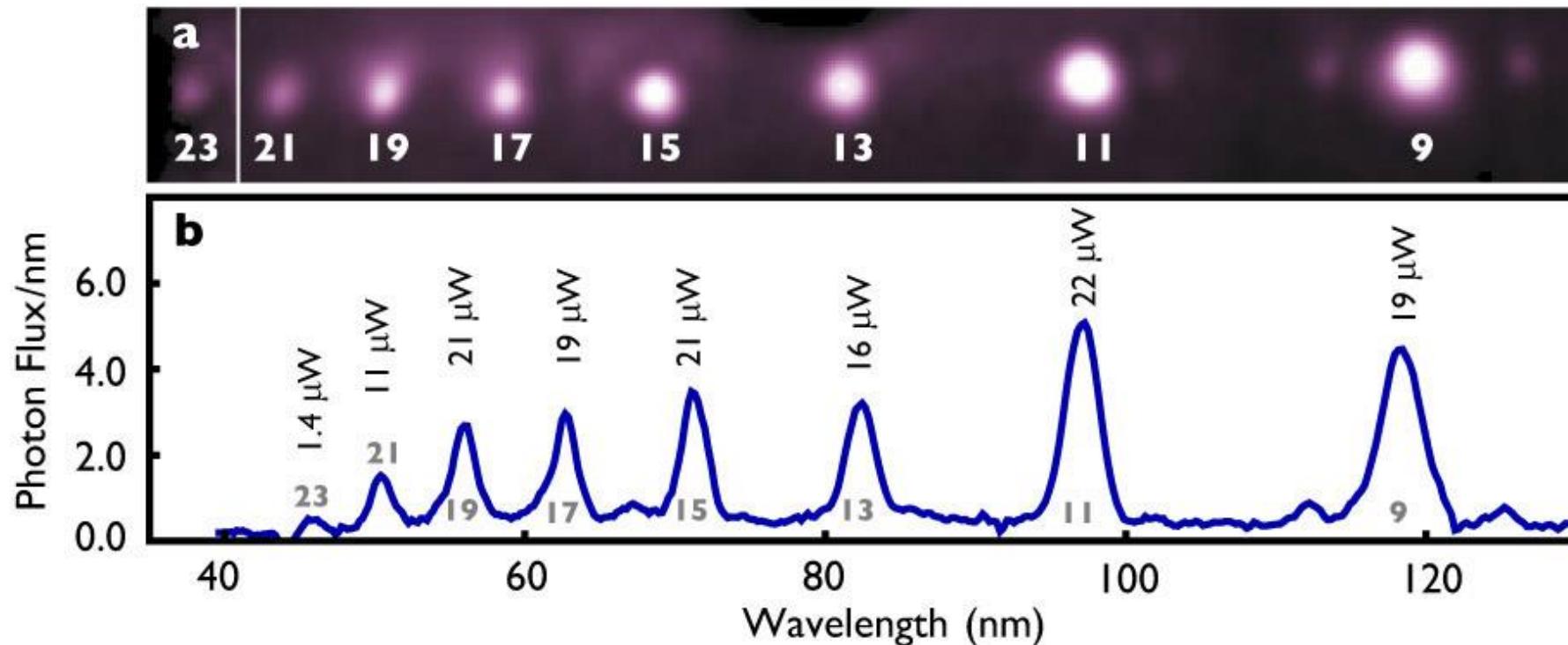
Only odd harmonics

Why are in an HHG spectrum

- (a) Peaks?
- (b) only odd-order peaks?

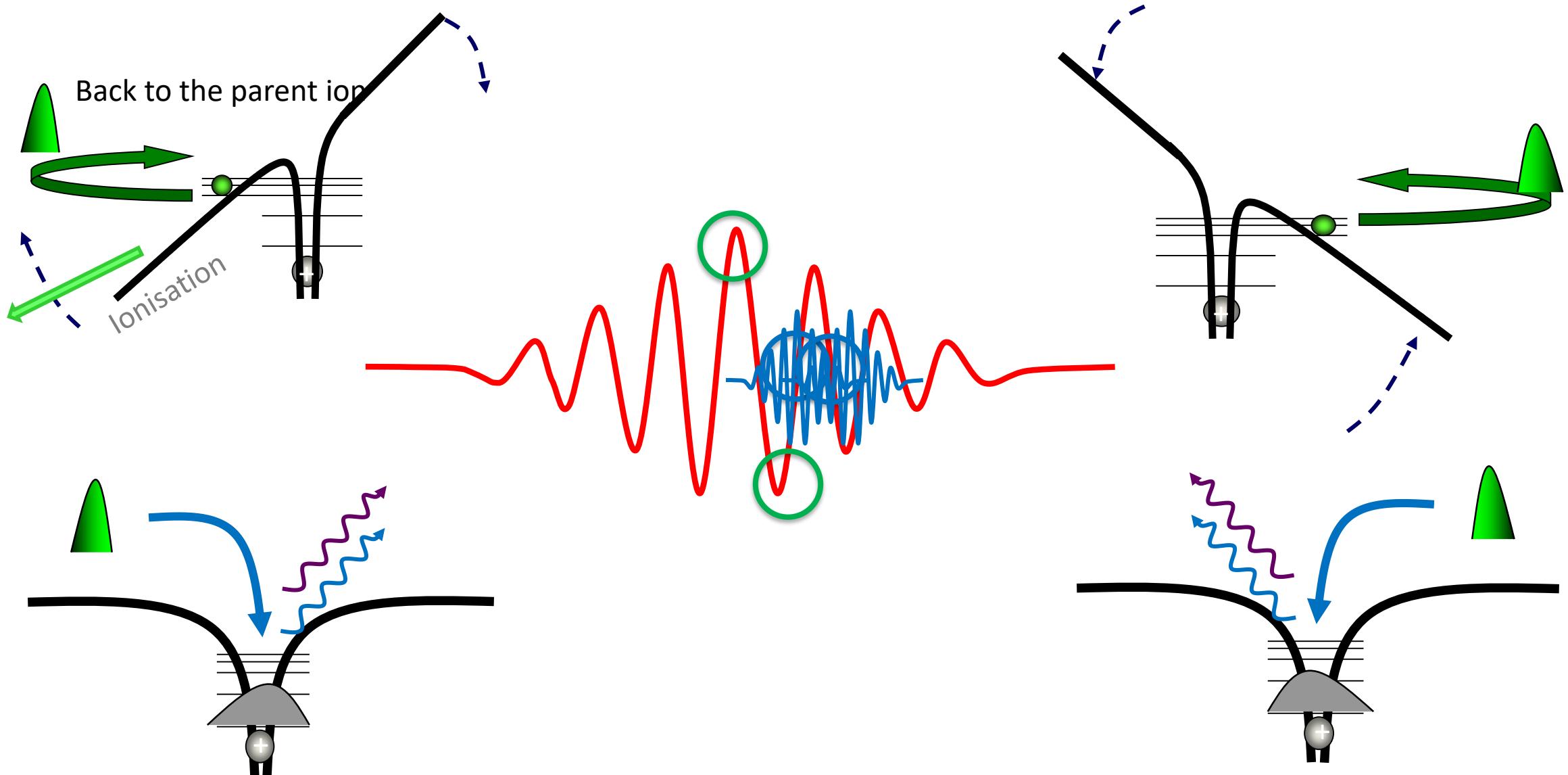
Peak structure in HHG spectra:

Fourier-relation: regular pattern in frequency domain
– must be regular process in time domain

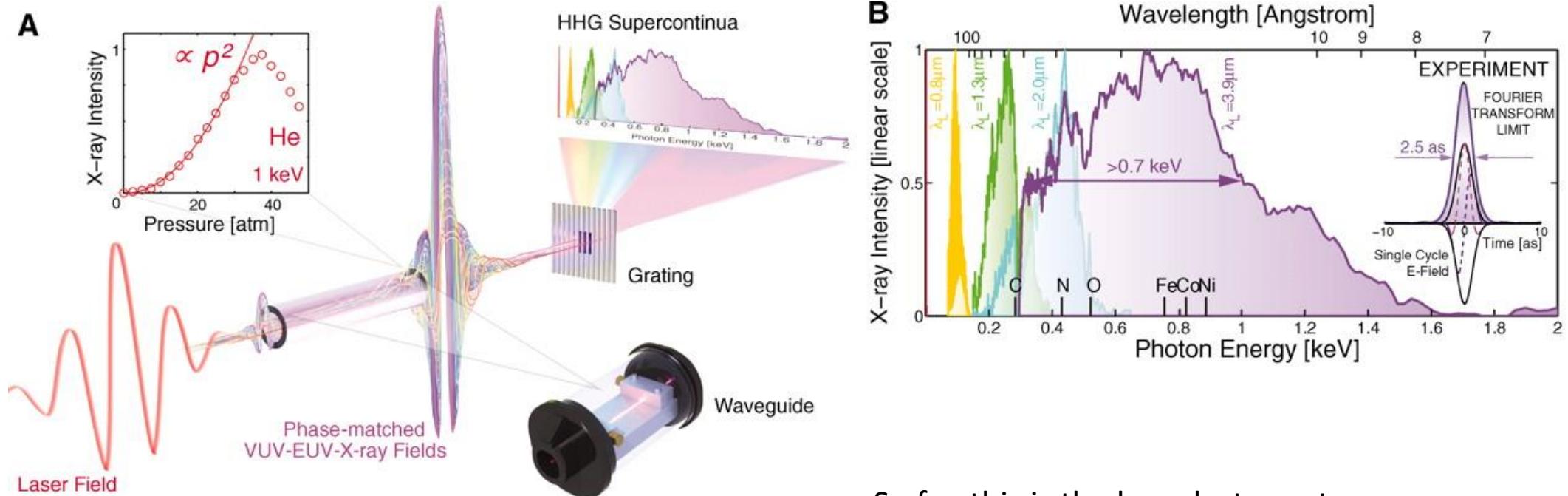


Taken from: A Cingöz, DC Yost, TK Allison, A Ruehl, ME Fermann, I Hartl, J Ye,
“Direct frequency comb spectroscopy in the extreme ultraviolet” Nature 482, 68 (2012)

Repeating process : every half-cycle (2x per optical cycle)



The „shortest” pulse!?



So far, this is the broadest spectrum
which would correspond to the shortest pulse;
however, no way for direct measurement

High Harmonics Generation (HHG) – Gas vs. condensed phase

Atomic/molecular gases

Dielectrics /semiconductors

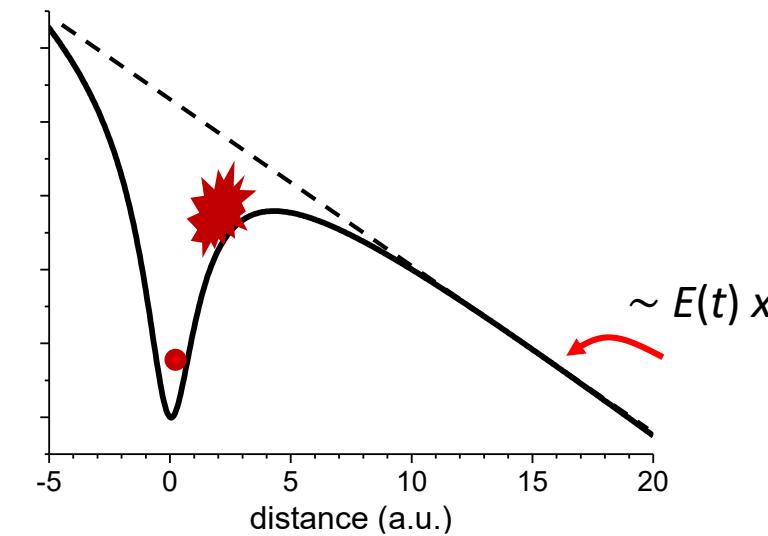
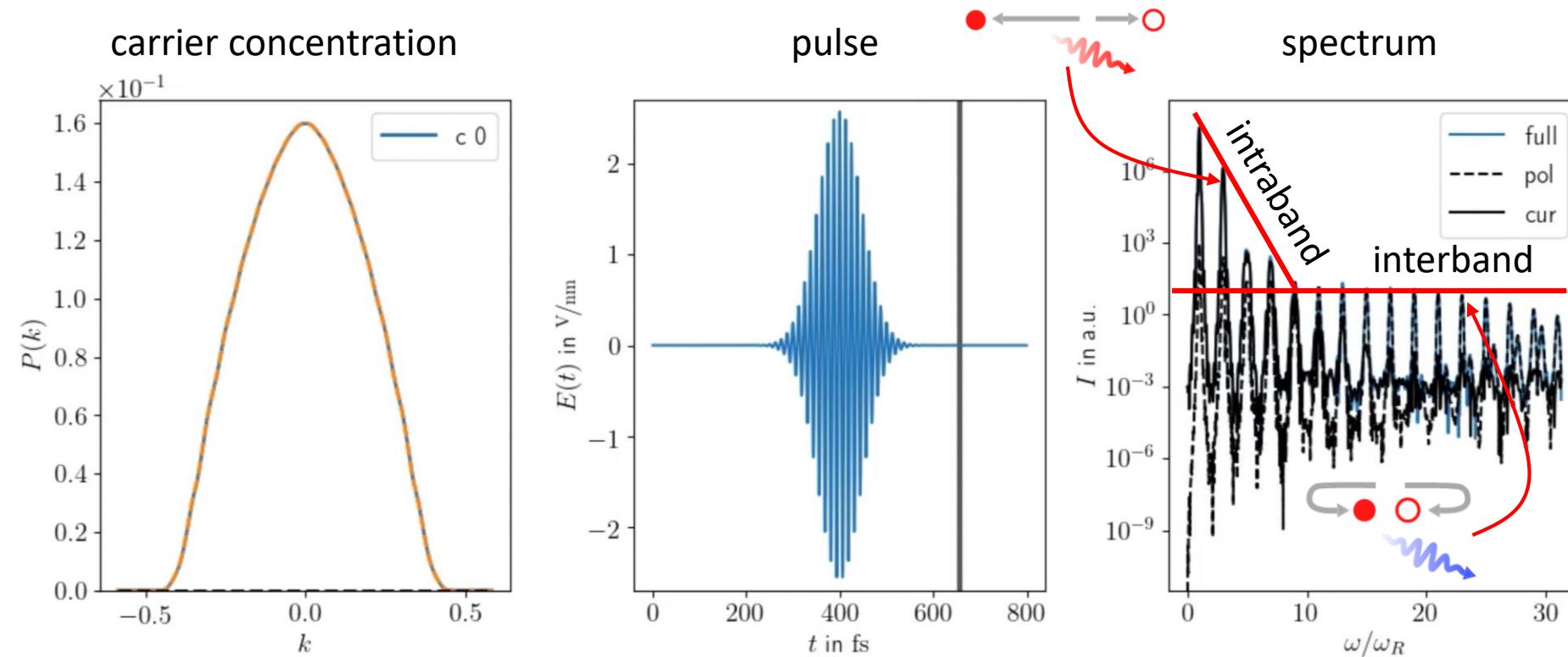


Figure: Taken from DOI:

High Harmonics Generation (HHG) in dielectrics - simulation

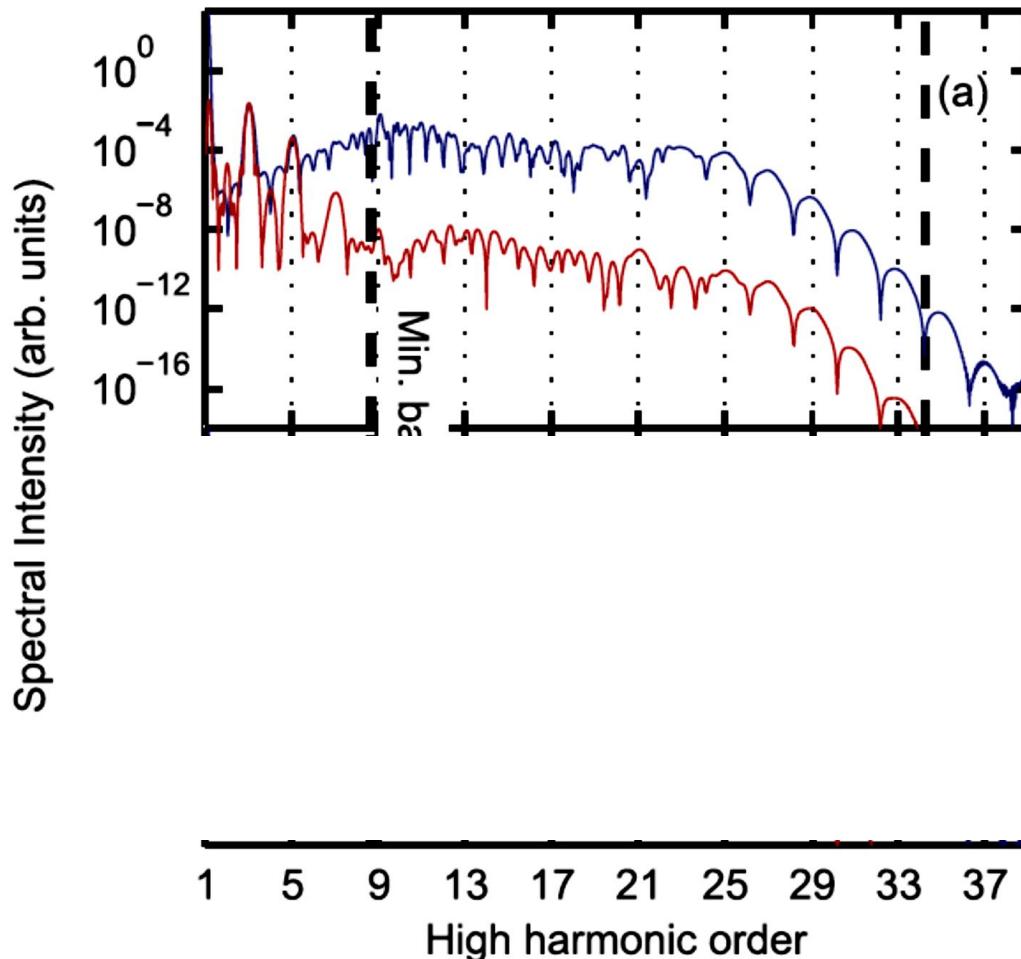


Simulations in momentum space based on Semiconductor Maxwell-Bloch Equations

Material: ZnO, gap energy 3.3eV (375nm) pulse: 100fs $\lambda=4\mu\text{m}$ $E_{\max}=2.3 \text{ V/nm}$

D. Golde, T. Meier, and S. W. Koch, High harmonics generated in semiconductor nanostructures by the coupled dynamics of optical inter- and intraband excitations, Phys. Rev. B 77, 075330 (2008).

The dephasing time



No dephasing time: no distinct harmonics

Introduction of dephasing times:

T_1 : decay time of carrier population;

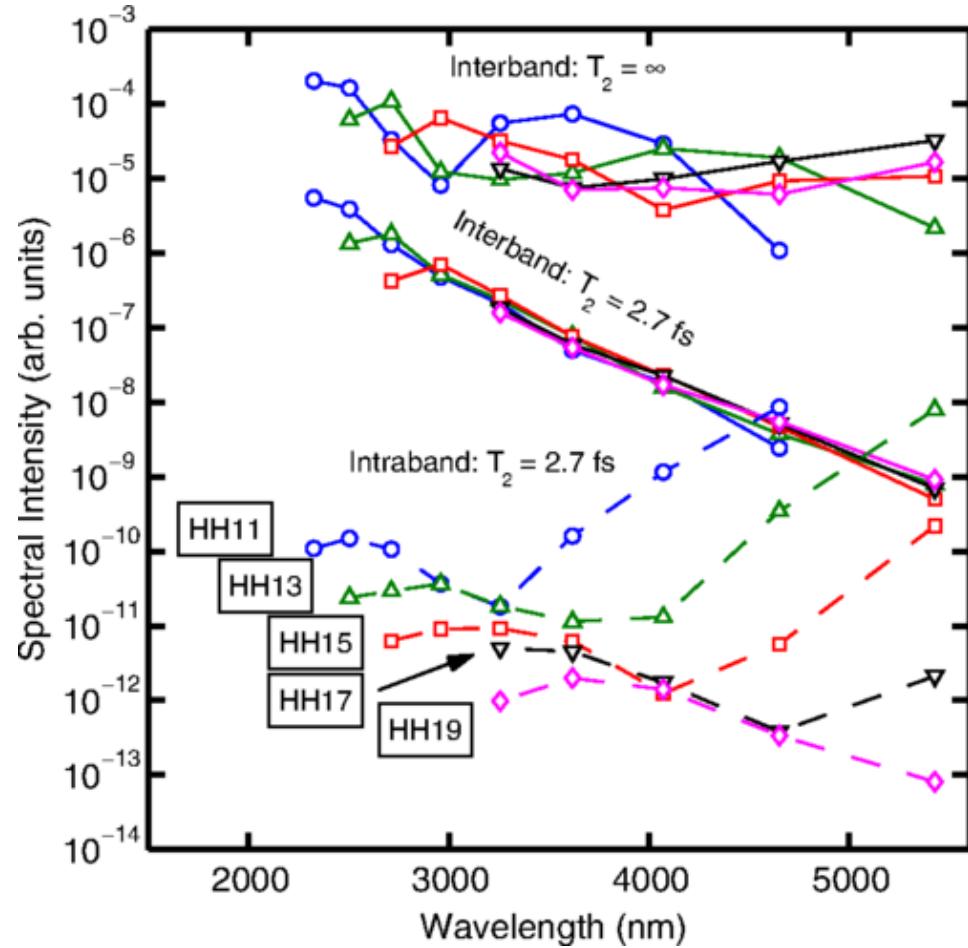
T_2 : decay time of the polarization (decay of quantum coherence in coherently excited system)

Phenomenological values for $T_2 \sim 2$ fs – less than a 1/4 of optical cycle (??)

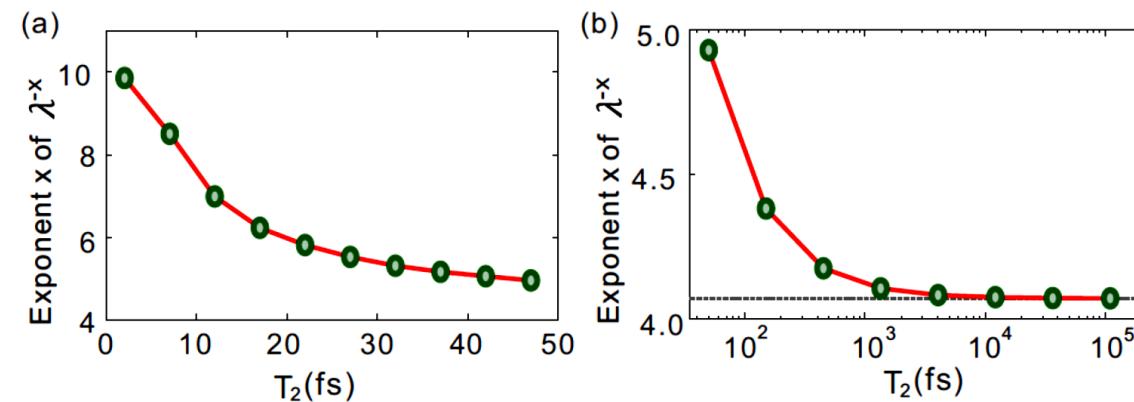
Necessary to match simulated and experimental spectra

The „dephasing time“

Dephasing defines the exponential decay of harmonic yield with driving wavelength



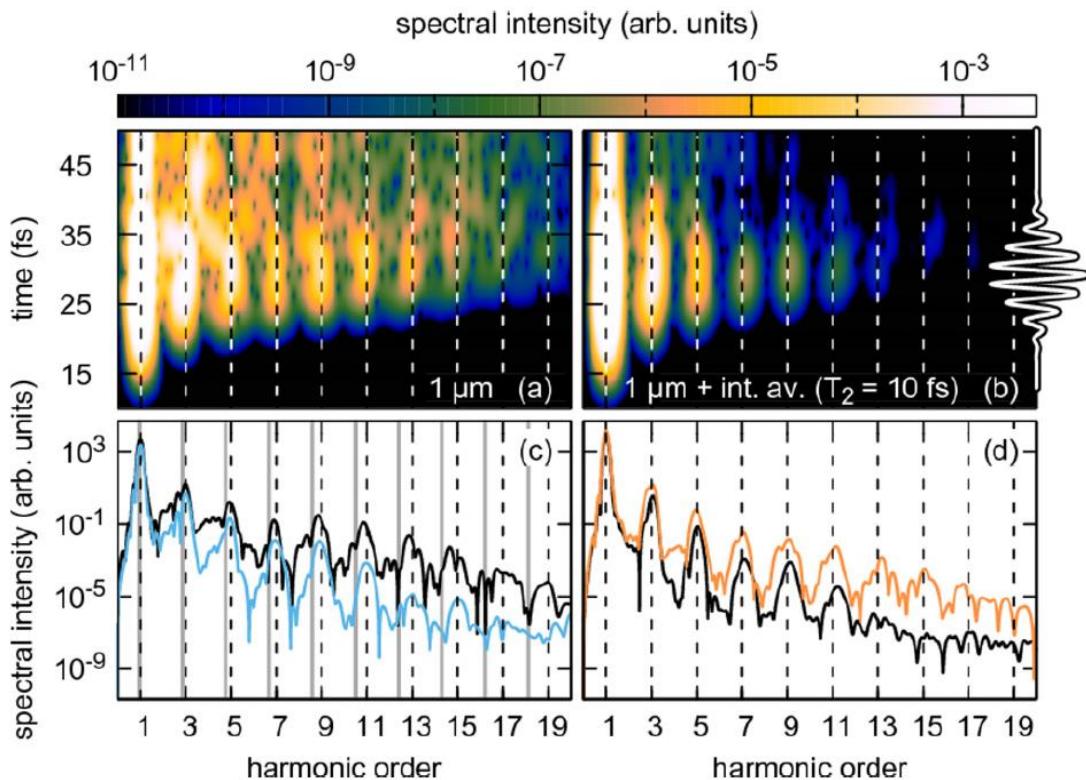
Vampa et al., PRL 113, 073901 (2014)



X. Liu, ... Peixan Lu, PRA 98, 063419 (2018)

- What is the wavelength dependence of HHG in solids?
- What is the origin of the dephasing?

Ultrafast dephasing time T_2 ?



What is the physical origin of such ultrafast dephasing?

Hypothesis: **propagation effects**: “Ultrafast microscopic dephasing rates of the order of $T_2 \approx 1$ fs previously invoked are **neither necessary nor justified** for forming a well-defined harmonic spectrum.”

->No dephasing or at least order of magnitude larger dephasing time + propagation effects!

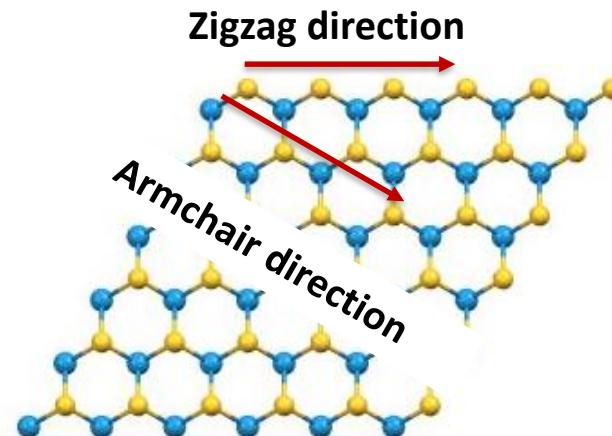
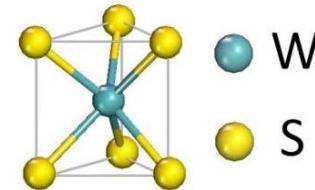
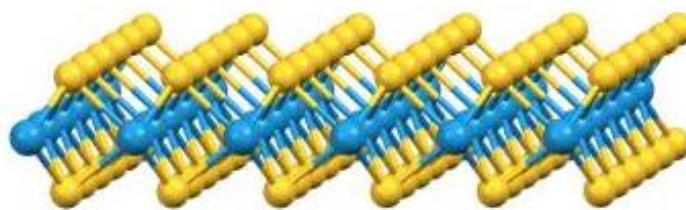
I. Floss, Yabana, Burgdöfer, PRA 97, 011401(R) (2018)

-- Let's investigate

Wavelength-dependence of HHG in thin samples

Samples

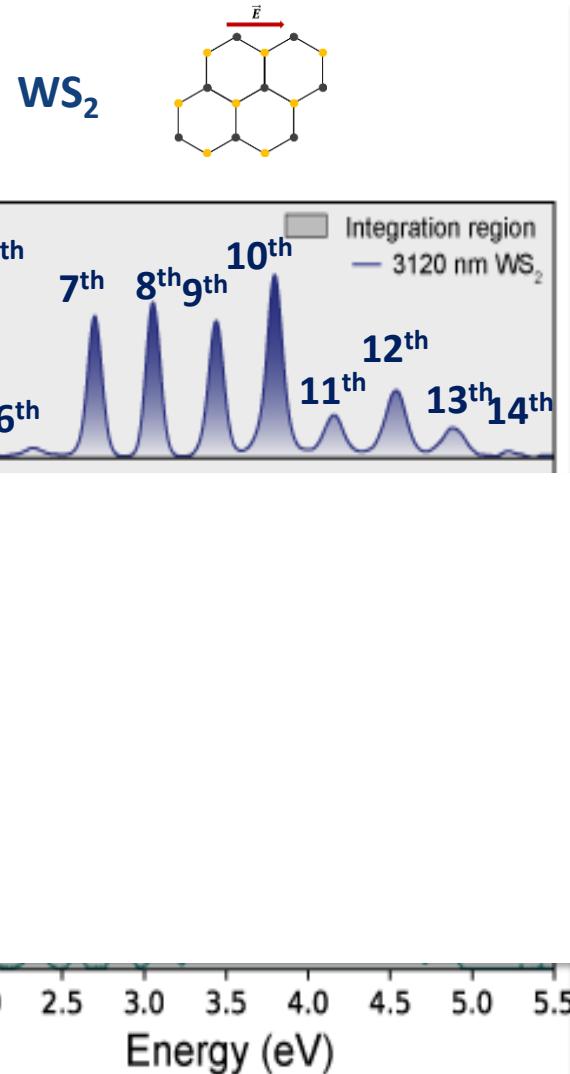
- Single atomic layer WS_2 or MoS_2
- 140 nm thick wurtzite polycrystalline CdSe film



Experiments by Daniil Kartashov

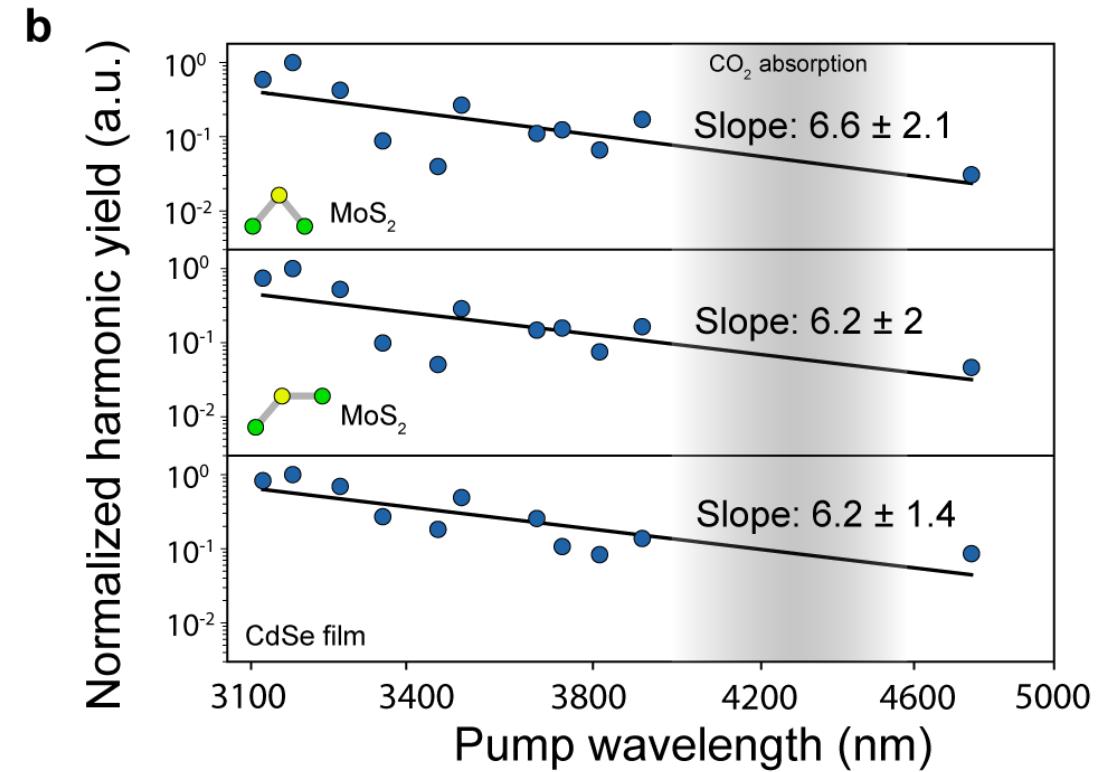
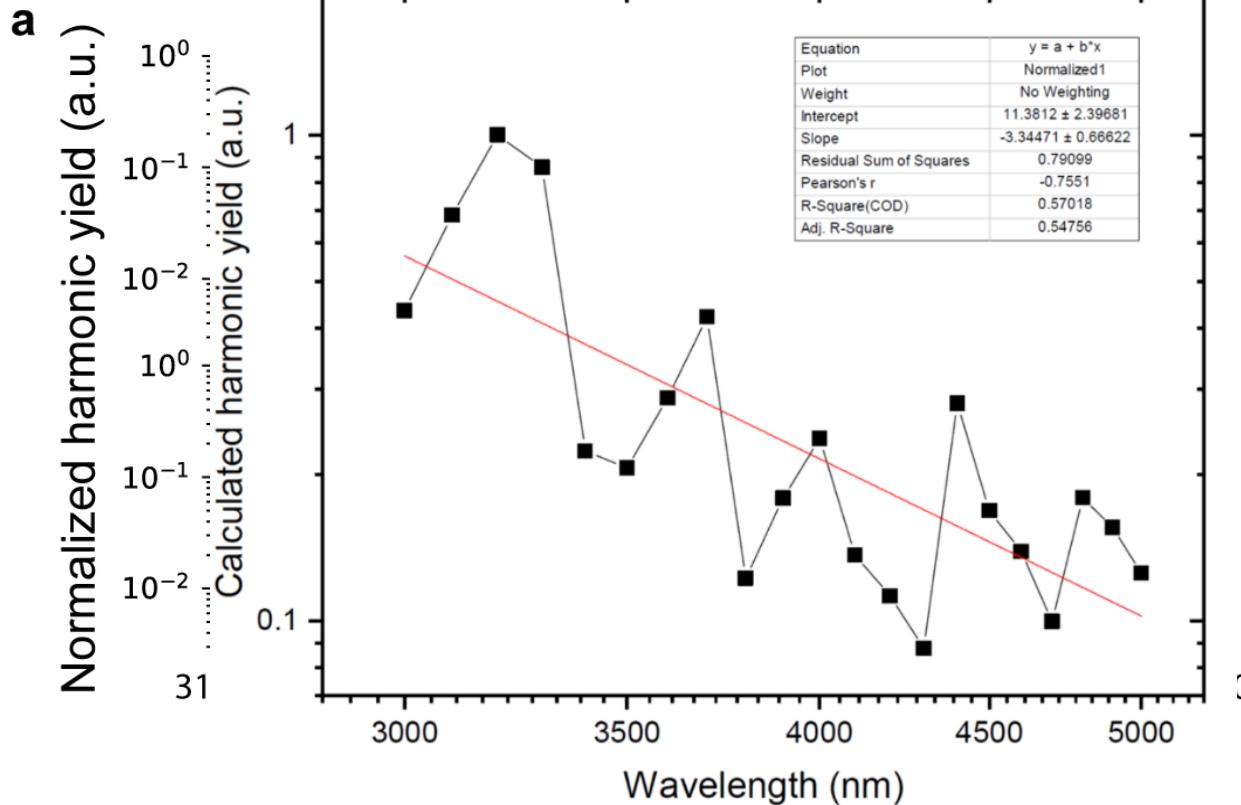
No propagation effects!

Experimental results



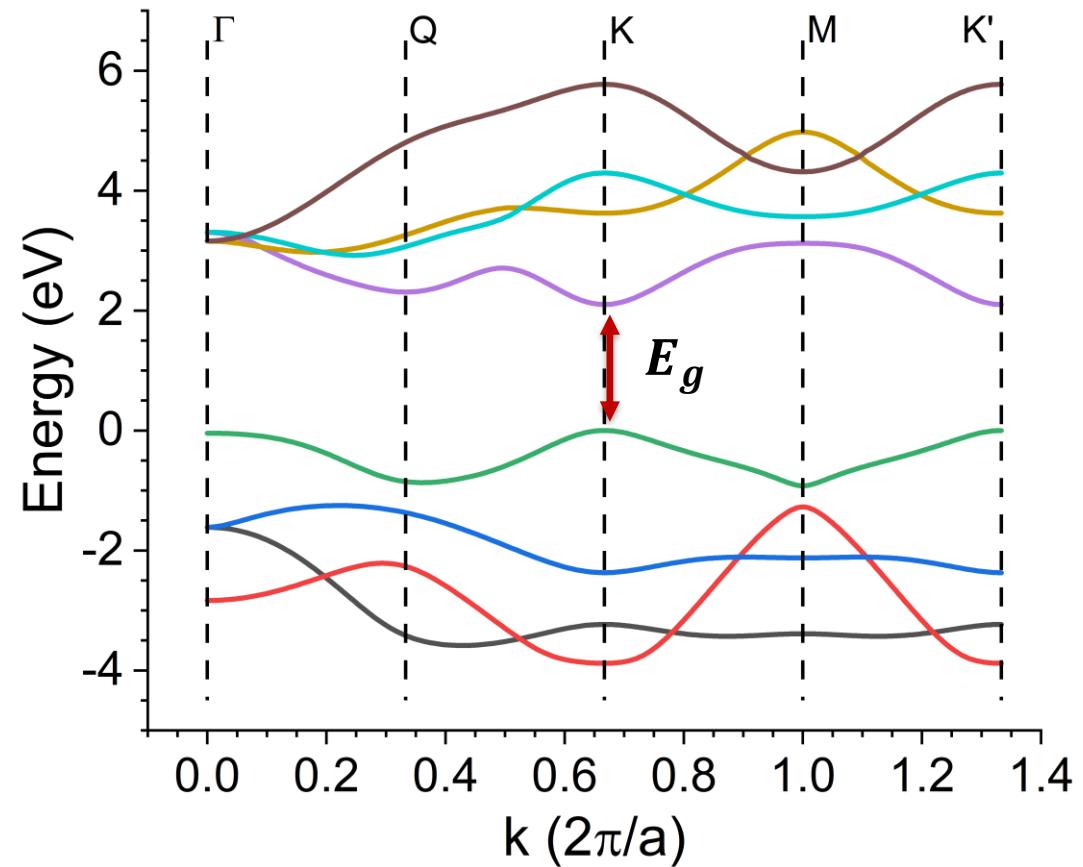
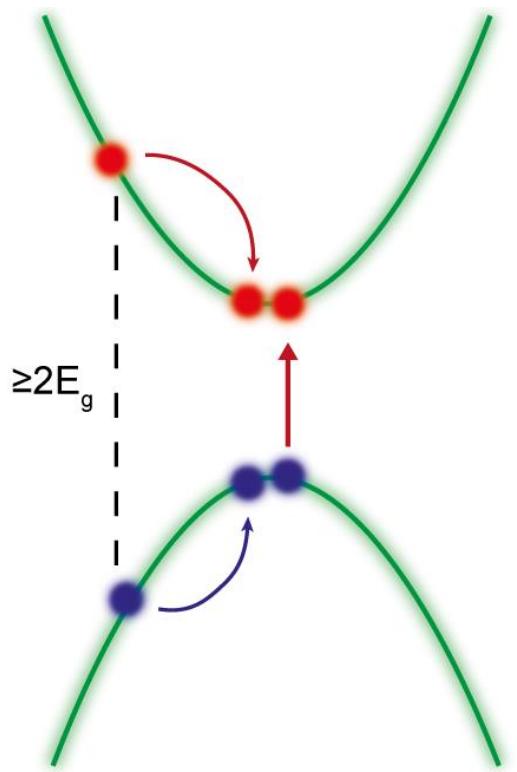
Integral harmonic yield in the range 2 (1.9) – 5.5 eV

Wavelength dependence in HHG



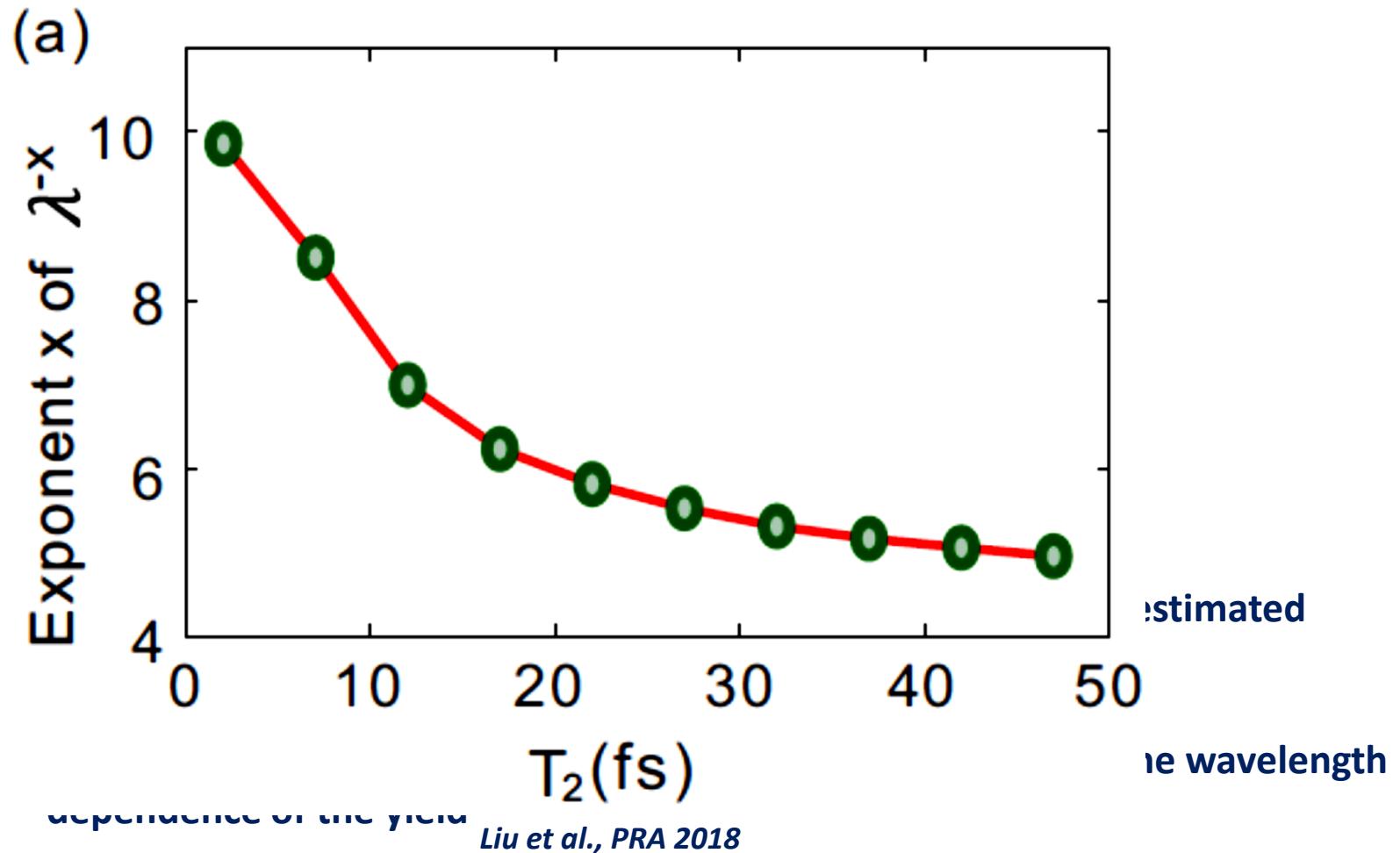
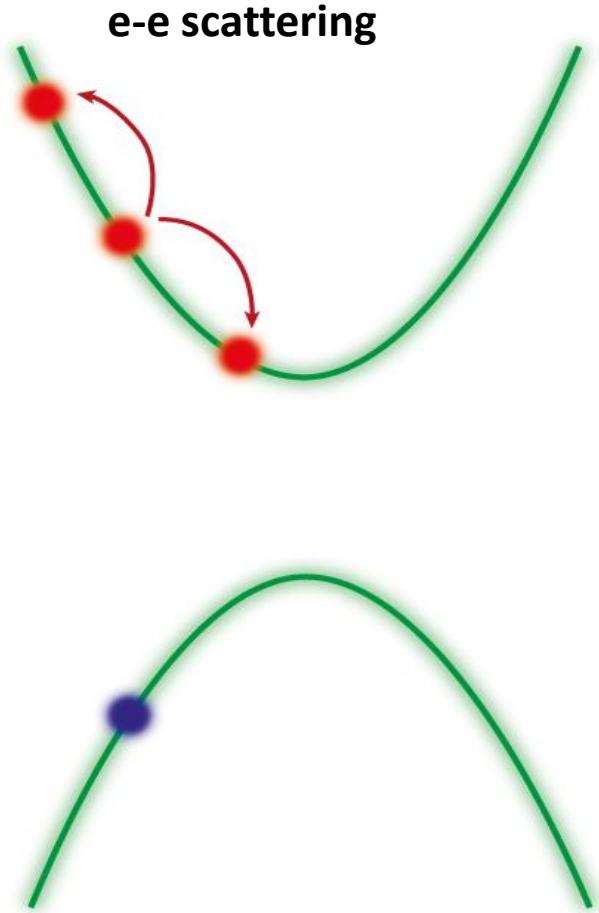
Numerical simulations without dephasing predict $\lambda^{-3.3}$ (rt-TDDFT) or λ^{-4} (SBE) dependence!

Origin of the dephasing: Carrier multiplication?

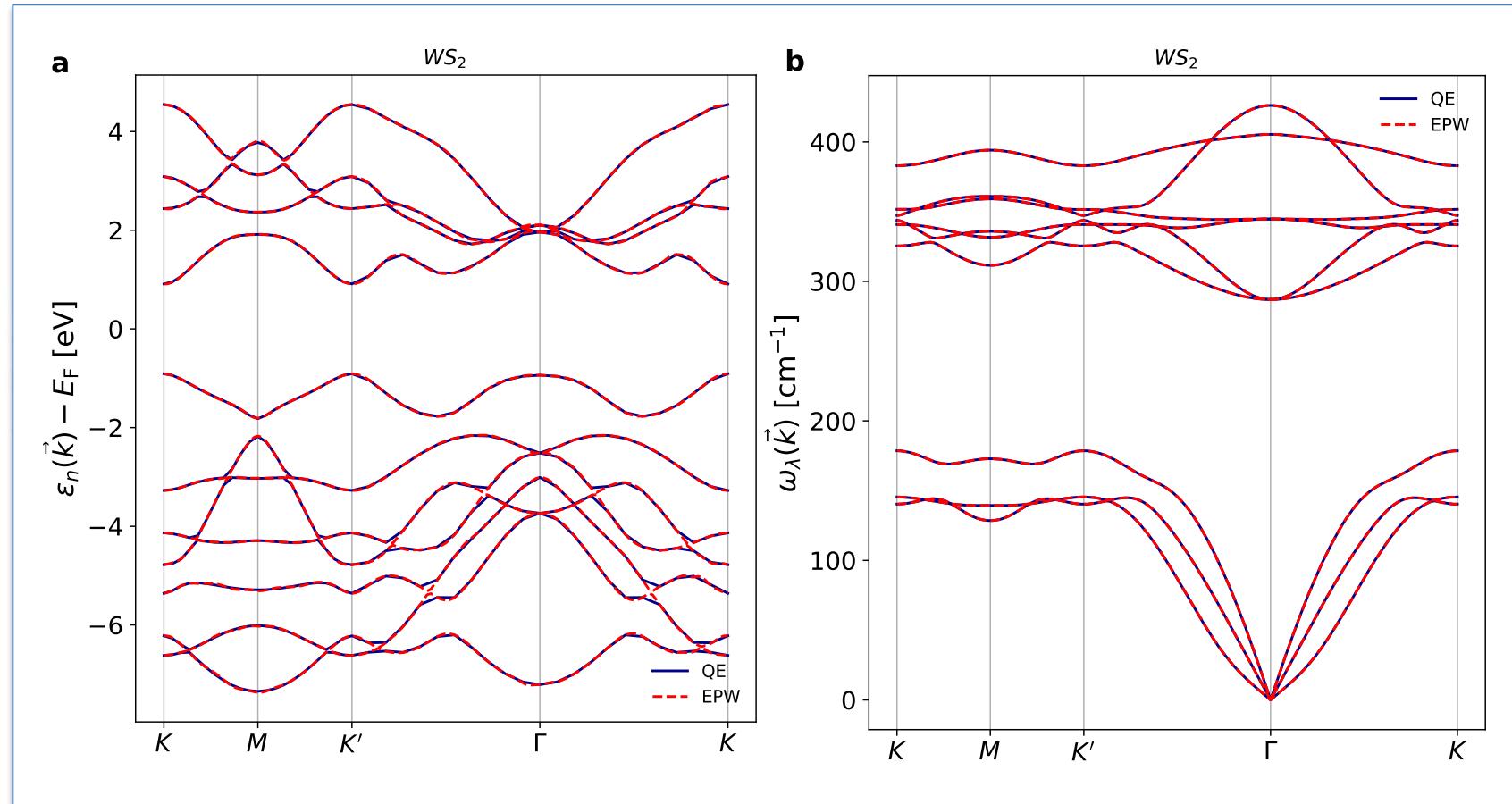
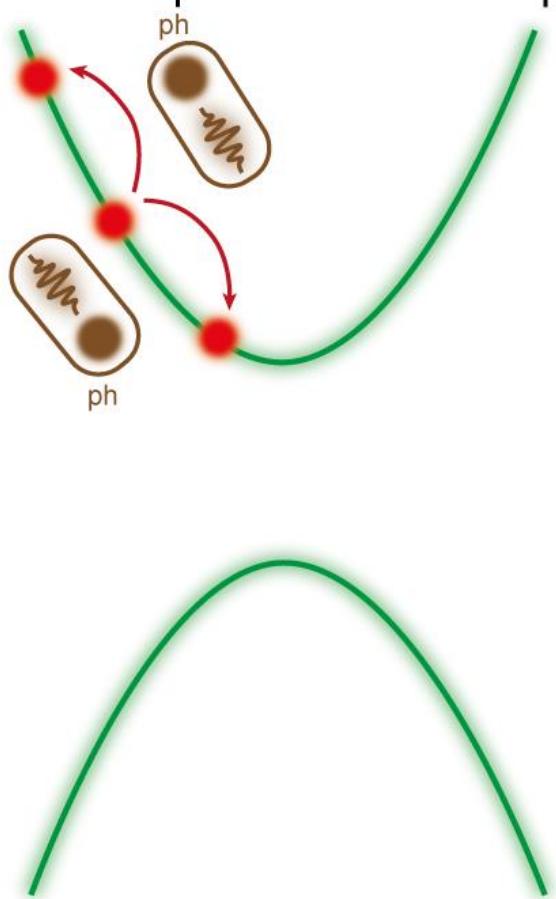


Requires kinetic energy $> 2 E_g$ - inefficient for electron motion within the band

Origin of the dephasing: e⁻ -e⁻ scattering?

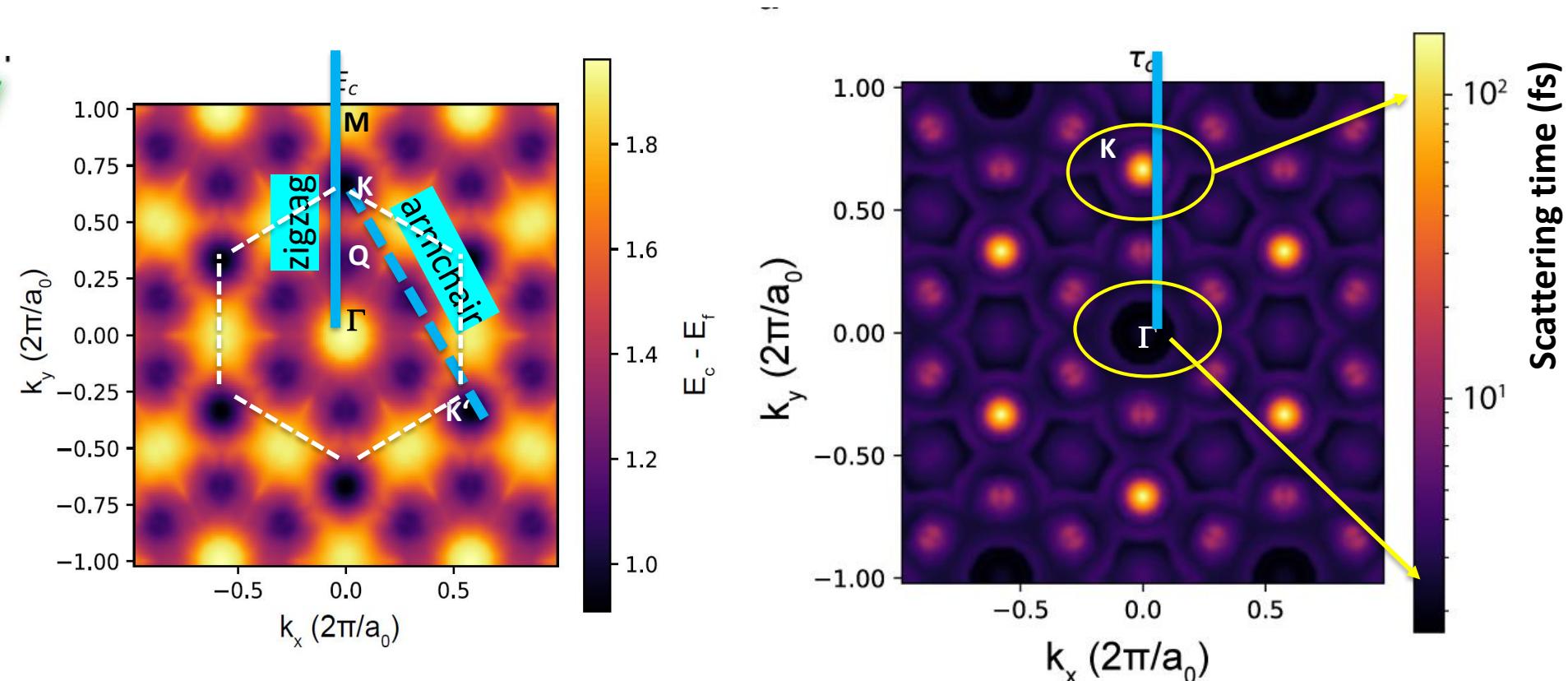
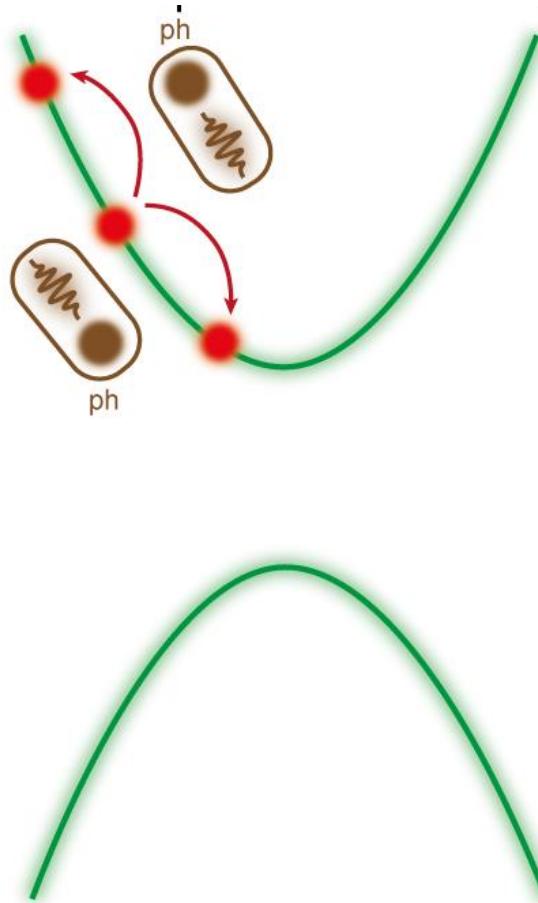


Origin of the dephasing: e⁻ -phonon scattering



A) Electronic band structure and **b)** Phonon dispersion of WS_2

Origin of the dephasing: e⁻ -phonon scattering

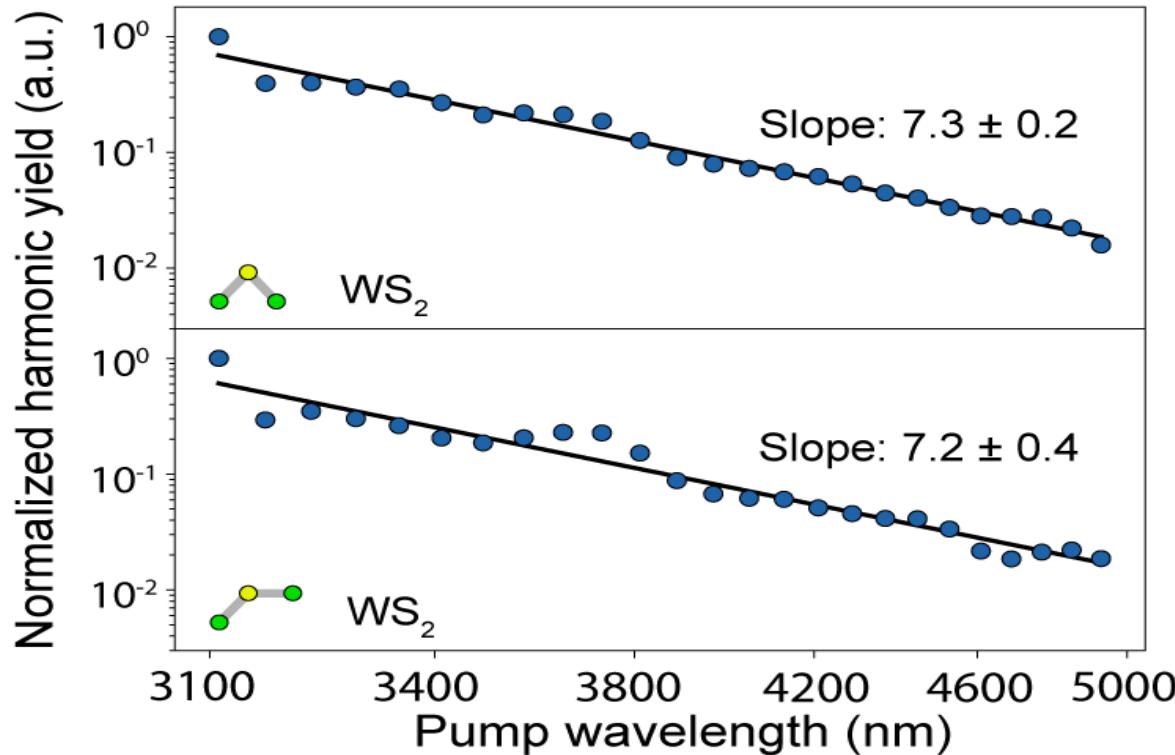


A) Electronic energy landscape (CB) and b) Calculated e-phonon scattering time (LOG-scale!) in WS₂

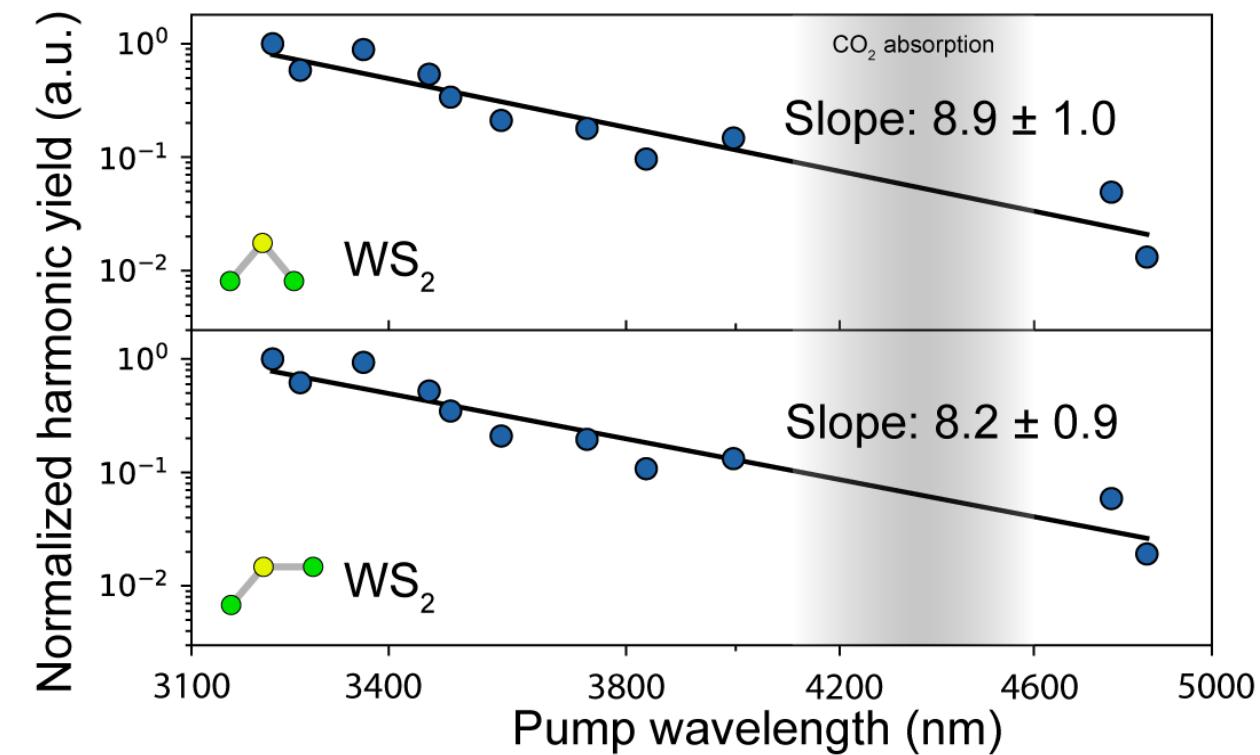
- e-phonon scattering time is highly dispersive $\rightarrow T_2(k)$
- e-ph scattering time drops from ~200 fs in the K-valley down to ~2 fs in a vicinity of Γ -point!

Numerical simulations

SBE simulations



Experiment



SBE simulations with ab-initio calculated $T_2(k)$ -match the experimental results!

STRONG FIELD MEETS QUANTUM OPTICS

Quantum description of (semiconductor) HHG



Collaboration partners:

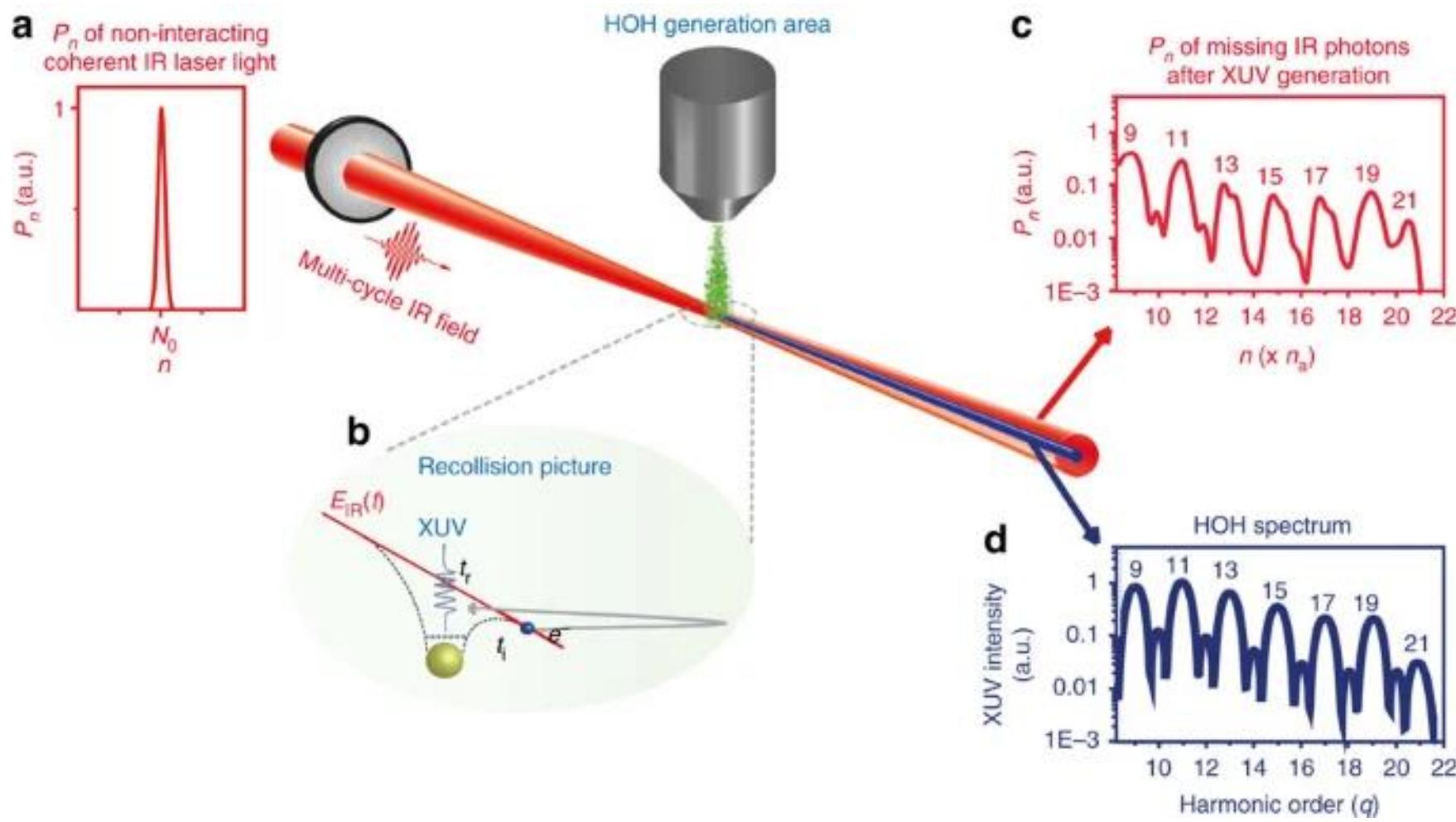
Prof. Jens Biegert (ICFO)

Prof. Ulf Peschel

Prof. Misha Ivanov (MBI Berlin)

Prof. Hamed Merdji (Paris)

Quantum Signatures in HHG – the pioneering experiment

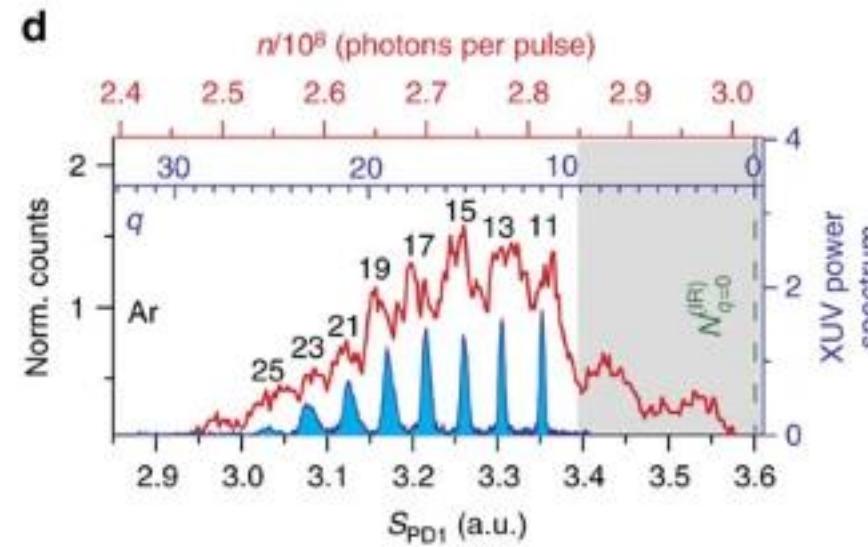
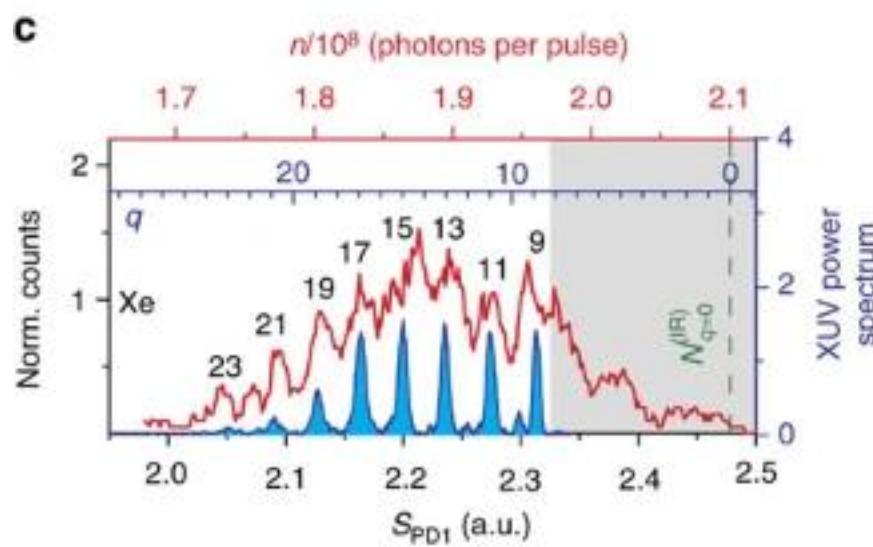
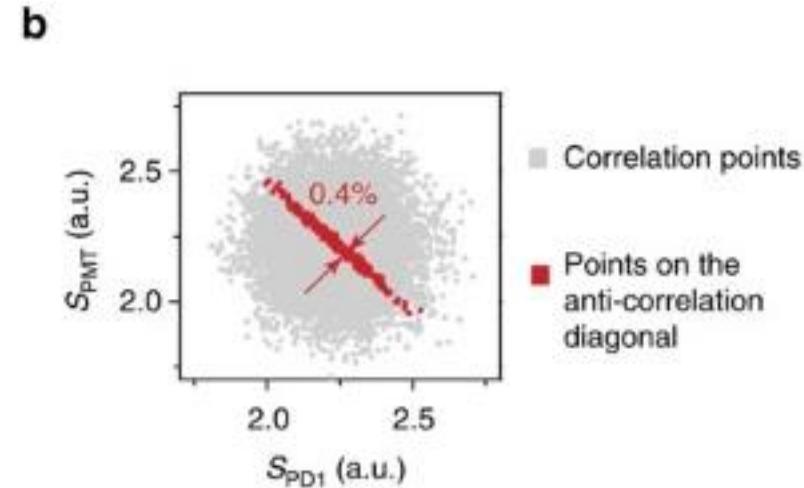
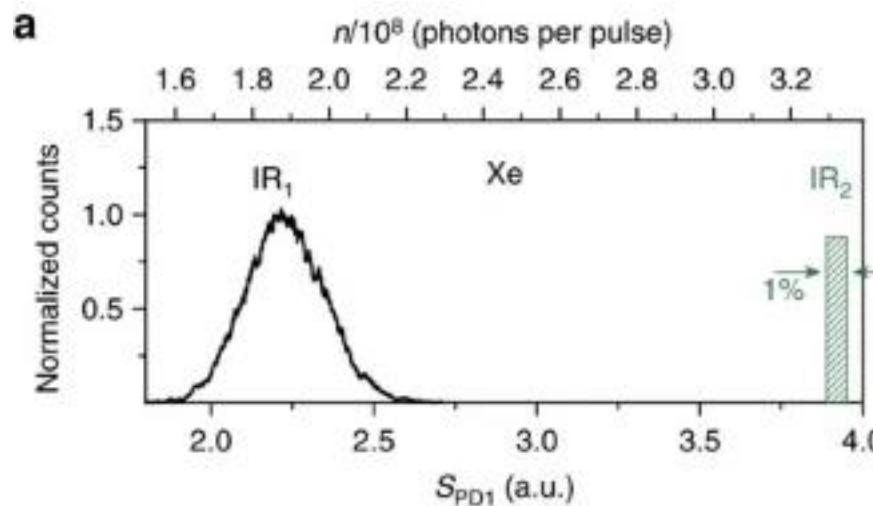


IR: 800 nm pulse, 0.6mJ
energy/pulse; ($\sim 8 \times 10^{13} \text{ W/cm}^2$),
 10^{15} photons/pulse

Xe gas jet – generating HH

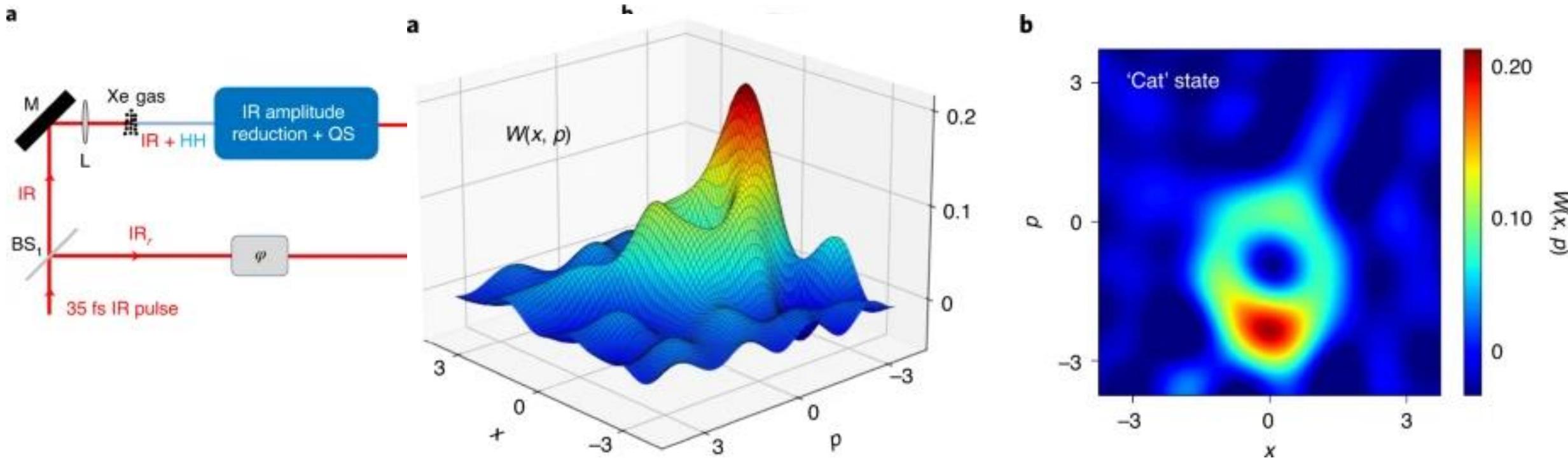
Afterwards: IR beam attenuated
by $\sim 10^6$

Quantum Signatures in HHG – the pioneering experiment



Approximately 10^8 photons per XUV pulse,
About 10^7 photons per harmonics (for 5 harmonics in the plateau region)

Generation of optical „cat“ states in HHG

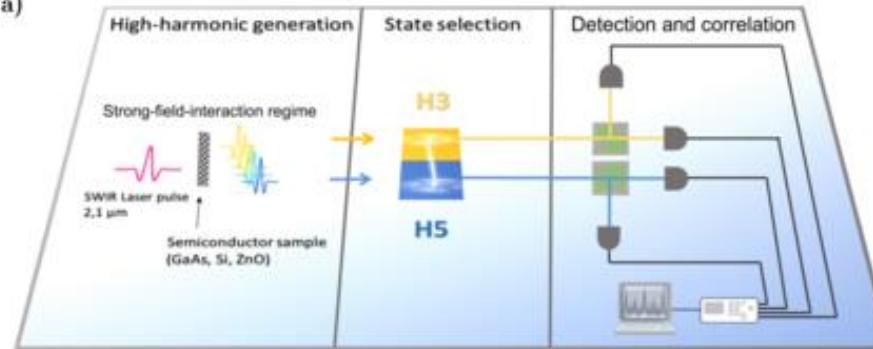


- Reconstruction of the transmitted fundamental radiation
- Nonclassicality (negative regions of the Wigner function)
- Obtained by conditioning

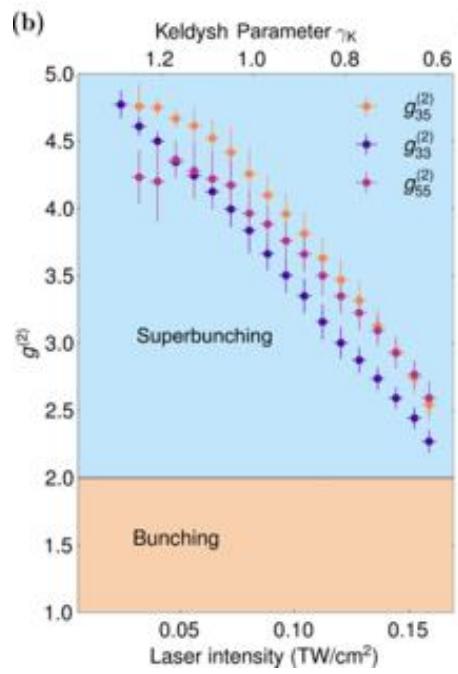
... so far: quantum properties of the transmitted (generating) fundamental (& to the HHs)

Quantum properties/entanglement of the harmonics

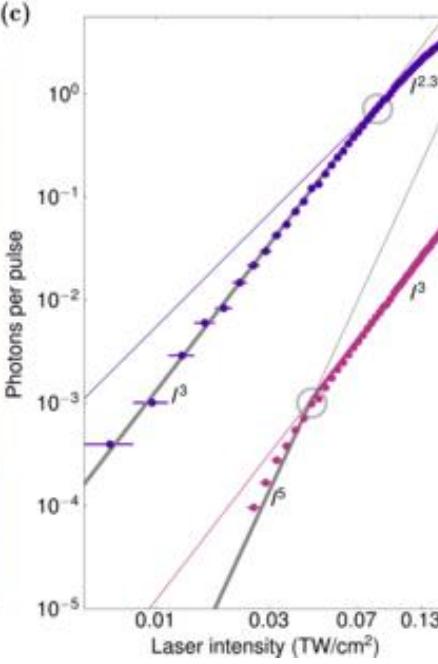
(a)



(b)

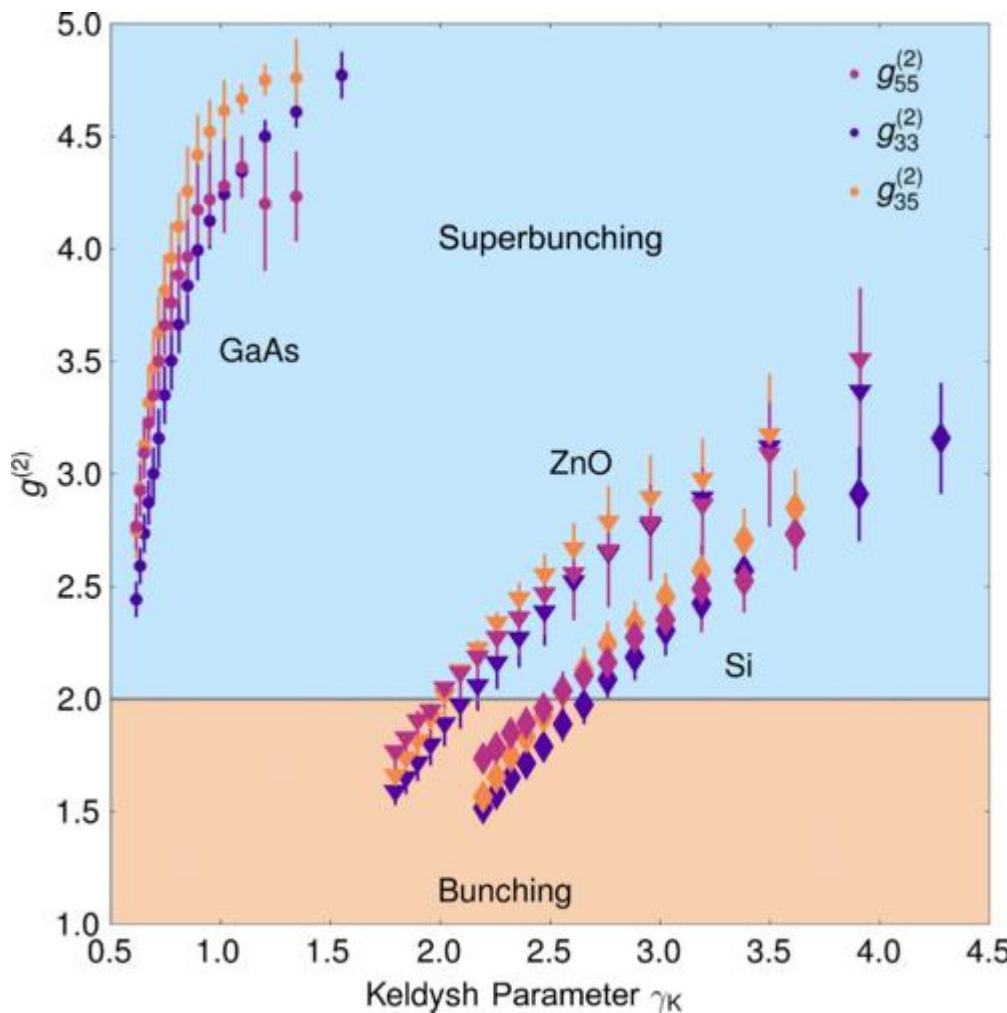


(c)



- HHG experiment in bulk semiconductors (GaAs Si, ZnO)
- Correlation $g^{(2)}$ measured ($g_{33}^{(2)}$, $g_{55}^{(2)}$ and $g_{35}^{(2)}$)
- $g^{(2)}$ changes as a function of laser intensity (Keldysh parameter)

Quantum properties/entanglement of the harmonics



For a single-mode bosonic state:

$g^{(2)}=1$ – Poissonian photon-number statistics (coherent state).

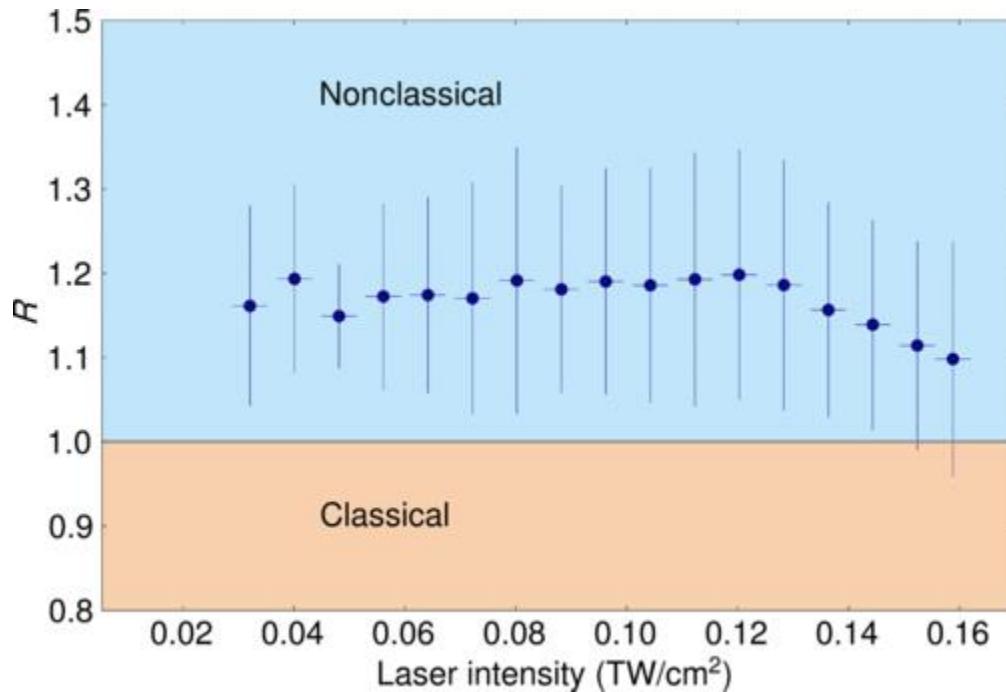
$g^{(2)}>1$ – super-Poissonian statistics – bunched arrival of photons

$g^{(2)}=2$ – Bose-Einstein

$g^{(2)}>2$ Nonclassical effects such as superbunching,

$g^{(2)}<g^{(2)}(\tau)$ is connected to photon antibunching, as often obtained from single-photon sources.

Quantum properties/entanglement of the harmonics



Cauchy-Schwartz inequality

$$g_{ii}^{(2)} g_{jj}^{(2)} < \left| g_{ij}^{(2)} \right|^2$$

$$R := \frac{\left| g_{ij}^{(2)} \right|^2}{g_{ii}^{(2)} g_{jj}^{(2)}}$$

How to theoretically describe quantum optics in the strong-field regime?

Exact Factorization: general case

$$i \dot{\Psi} = \hat{H} \Psi$$

$$\Psi(\mathbf{x}, \mathbf{y}, t) = \Phi(\mathbf{x}, \mathbf{y}, t) \cdot G(\mathbf{y}, t)$$

$$\hat{H} = \left[\hat{H}_1(\mathbf{x}) + \hat{H}_2(\mathbf{y}) + \hat{W}_{int}(\mathbf{x}, \mathbf{y}, t) \right]$$

Abedi, A., Maitra, N. T., Gross, E. K. U., Phys. Rev. Lett. 105, 123002 (2010)

Exact Factorization: quantum optical description of laser-driven systems*

$$\Psi(\mathbf{x}, \mathbf{y}, t) = \Phi(\mathbf{x}, \{\beta \mathbf{y}\}, t) \cdot G(\mathbf{y}, \beta, t) + O(\beta^s),$$

$$\Phi(\mathbf{x}, \{\beta \mathbf{y}\}, t) = F(\mathbf{x}, \{\beta \mathbf{y}\}, t) \cdot \exp \left[i \int_0^t \langle \hat{H}_1 + \hat{W}_{int} \rangle_F d\tau \right],$$

$$i \dot{F} = \left[\hat{H}_1 + \hat{W}_{int}(\mathbf{x}, \{\beta \mathbf{y}\}, t) \right] F,$$

$$i \dot{G} = \left[\hat{H}_2 + \langle \hat{H}_1 + \hat{W}_{int} \rangle_F \right] G.$$

Coordinate-scaling parameter $\beta \ll 1$

$$\beta \propto \sqrt{\frac{m}{M}}, \quad \beta \propto \frac{1}{\sqrt{V_q}}, \quad \dots$$

Parametric Factorization: light-matter problem*

(Interaction representation, plane wave 1+1 case, zero initial phase, SF/coherent)

$$i\dot{\Psi} = \hat{H}\Psi , \quad \hat{H} = \frac{1}{2} \left(\hat{\vec{p}} - \hat{\vec{A}} \right)^2 + U(\vec{r}, t) ,$$

$$\hat{\vec{A}} = -\mathbf{x}_0\{\beta q\} \cos(\kappa z - \omega t)$$

$$\Psi_0 = \Phi_0(\vec{r}) \cdot G_c(q), \quad N_0 \gg 1. \quad A_0 = \beta\sqrt{2N_0}.$$

$$\beta = c\sqrt{2\pi/\omega V}$$

Coordinate-scaling parameter:

$$i\dot{F} = \left[\frac{1}{2} \left(\hat{\vec{p}} - \hat{\vec{A}}_{par} \right)^2 + U(\vec{r}, t) \right] F ,$$

$$i\dot{G} = \left\langle \frac{1}{2} \left(\hat{\vec{p}} - \hat{\vec{A}} \right)^2 + U(\vec{r}, t) \right\rangle_F G .$$

How to theoretically describe quantum optics in the strong-field regime?

Evolution of the light quantum states under the back-action of the intraband current (interaction picture):

$$\frac{\partial}{\partial t} |G\rangle = n_e E_c \left(- \sum_j \frac{e}{c} \hat{A}_j(t) \right) |G\rangle$$

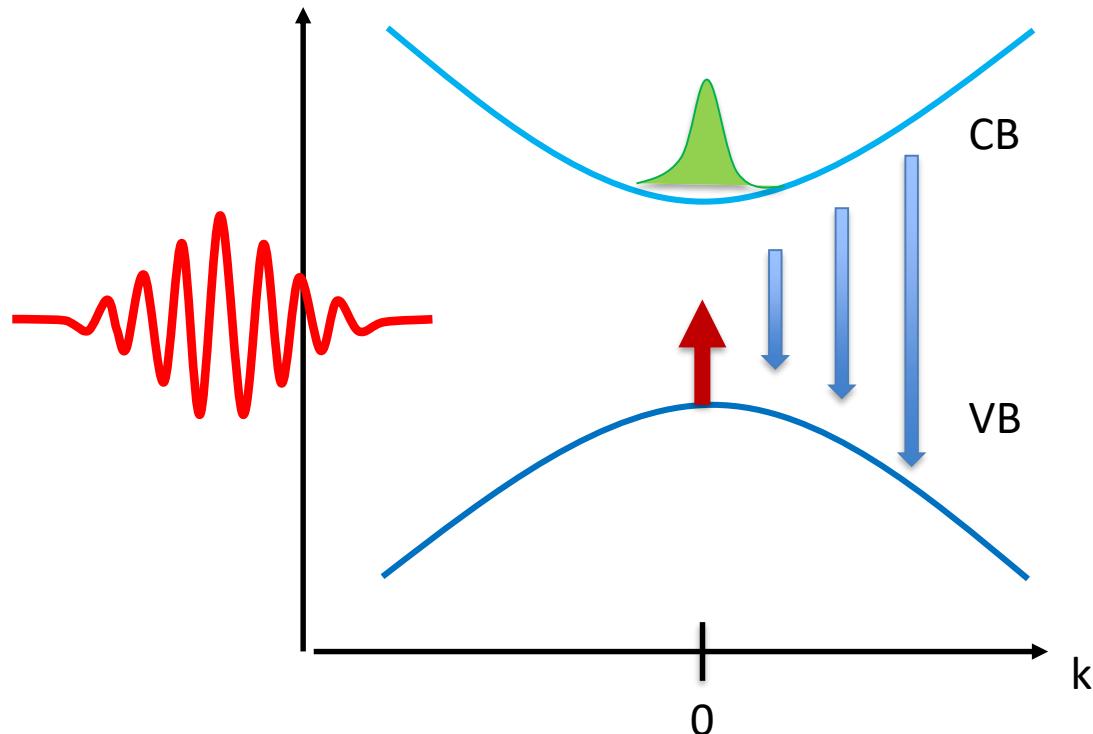
Vector potential operator:

$$\begin{aligned} \hat{A}(t) &= \hat{A}_L(t) + \sum_{j \geq 2} \hat{A}_j(t) \\ &= \sqrt{\frac{2\pi c^2}{\omega_L V}} \cos(\omega_L t) \hat{Q}_L + \sum_j \sqrt{\frac{\pi c^2}{\omega_j V}} [\hat{a}_j e^{-\omega_j t} + \hat{a}_j^\dagger e^{\omega_j t}]. \end{aligned}$$

$$i \frac{\partial}{\partial t} |G\rangle = \left[n_e E_c \left(\frac{e}{c} \hat{A}_L(t) \right) + n_e \sum_j \frac{e}{c} \hat{A}_j(t) \cdot \frac{\partial E_c}{\partial K} \Big|_{K=\frac{e}{c} \hat{A}_L} \right] |G\rangle$$

Non-classical light generation in semiconductor HHG

HHG in a semiconductor; intraband current contribution (below-bandgap harmonics)



Pauli Fierz Hamiltonian

$$\hat{H} = n_e E_c \left(\hat{\vec{p}} - \sum_j \frac{e}{c} \hat{\mathcal{A}}_j \right) + \sum_j \omega_j \hat{N}_j,$$

Conduction band
dispersion $E_c(k)$

Quantized
electromagnetic
field modes j

Approximation: quantum evolution of light field*,
treating intraband-current back-reaction as a finite-
order perturbation

*I. Gonoskov, S. Gräfe, "Light-matter quantum dynamics of complex laser-driven systems", *J. Chem. Phys.* 154, 234106 (1-5) (2021).

Non-classical light generation in semiconductor HHG

Separation: radiation field and field-dressed semiconductor

Initial state of light: product of coherent state (fundamental of the laser) and vacuum states (harmonic modes upto cutoff)

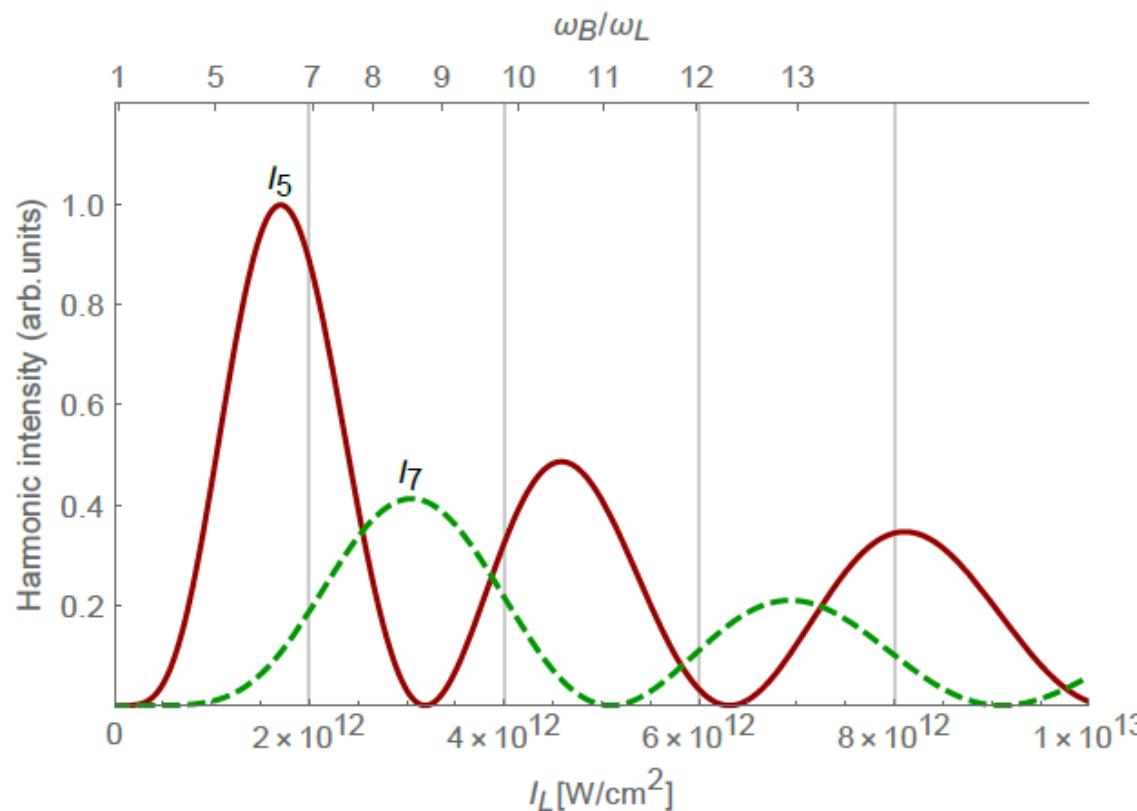
$$|G\rangle = |a_{Laser}\rangle \otimes |0_j\rangle$$

$$i\frac{\partial}{\partial t}|G\rangle = \left[n_e E_c \left(\frac{e}{c} \hat{A}_L(t) \right) + n_e \sum_j \frac{e}{c} \hat{A}_j(t) \cdot \frac{\partial E_c}{\partial K} \Big|_{K=\frac{e}{c} \hat{A}_L} \right] |G\rangle.$$

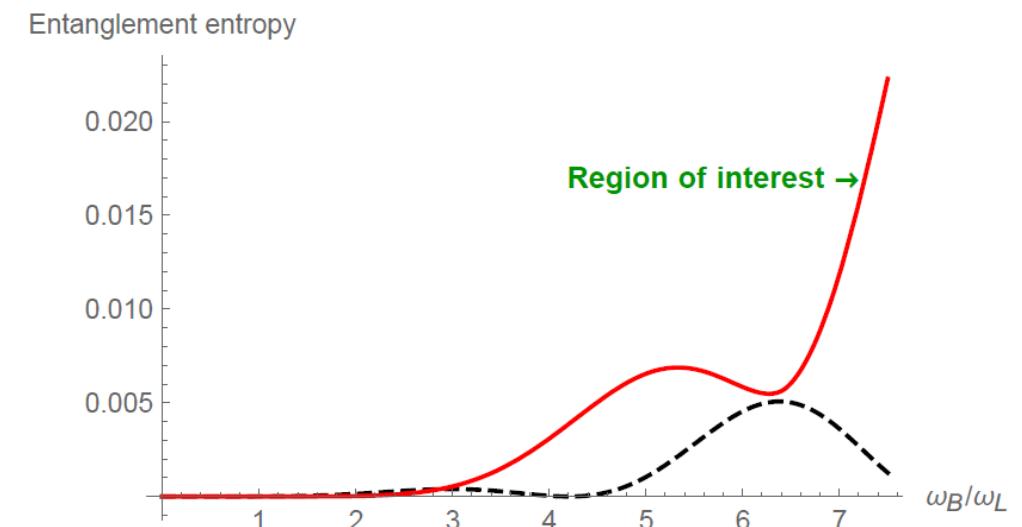
Equation is linear with respect to non-local operators (momentum quadrature operators) – analytical solutions

I. Gonoskov, R. Sondenheimer, ...S. Gräfe, „Nonclassical light generation and control from laser-driven semiconductor intraband excitations“, Phys. Rev. B 109, 125110 (2024)

Nonclassical properties of semiconductor HHG

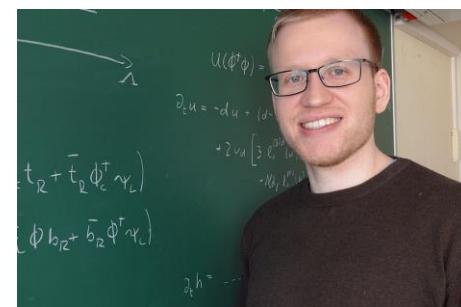


$$G \sim G_0(\vec{Q}) e^{\delta_3 Q_L Q_3} e^{\delta_5 Q_L Q_5} \dots,$$



Many open questions

- Why are there actually quantum signatures in such intense driving fields? Should be all classical? Quantum character due to measurement (conditioning) or intrinsic?
- How to experimentally access ‘quantumness’? Interferometric measures?
- How to properly characterize bright, entangled squeezed quantum light (von Neumann entropy not an ideal measure)?
- Why does ‘quantumness’ surveil? So much decoherence everywhere... (and how to properly include decoherence...?)
- Numerical model (incl. dephasing time)
- Are there some ‘sweet spots’ for harnessing quantum light?
- What about squeezed light?



Together with: Dr. René Sondenheimer
(Quantum Information Theory)

Dr. Ivan Gonoskov

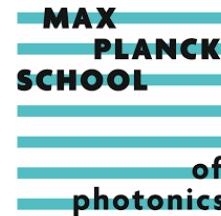
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